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The computational power of random quantum circuits in arbitrary geometries

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Empirical evidence for a gap between the computational powers of classical and quantum computers has been provided by experiments that sample the output distributions of two-dimensional quantum circuits. Many attempts to close this gap have utilized classical simulations based on tensor network techniques, and their limitations shed light on the improvements to quantum hardware required to frustrate classical simulability. In particular, quantum computers having in excess of ~ 50 qubits are primarily vulnerable to classical simulation due to restrictions on their gate fidelity and their connectivity, the latter determining how many gates are required (and therefore how much infidelity is suffered) in generating highly-entangled states. Here, we describe recent hardware upgrades to Quantinuum's H2 quantum computer enabling it to operate on up to 56 qubits with arbitrary connectivity and 99.843(5)% two-qubit gate fidelity. Utilizing the flexible connectivity of H2, we present data from random circuit sampling in highly connected geometries, doing so at unprecedented fidelities and a scale that appears to be beyond the capabilities of state-of-the-art classical algorithms. The considerable difficulty of classically simulating H2 is likely limited only by qubit number, demonstrating the promise and scalability of the QCCD architecture as continued progress is made towards building larger machines.

I. INTRODUCTION

It is widely expected that the computational power of quantum computers will only be fully realized by using quantum error correction (QEC). However, a significant gap exists between the capabilities of all existing quantum computing architectures (e.g., trapped-ions, superconducting qubits, neutral atoms, etc.) and the requirements to perform large scale error-corrected algorithms. To close this gap, desirable physical properties for a quantum computing architecture can readily be identified: all else being equal, it is generally better to have more qubits, lower physical error rates, higher connectivity, and faster clock speed. An honest assessment of the state of the field — supported empirically by the sheer variety of technologies under development — is that no one architecture is uniformly superior to the others with respect to all of these properties, each having strengths that can plausibly compensate for its weaknesses. For example, recent research into low-density parity check codes [1] suggests that high connectivity may greatly reduce the qubit resource requirements for QEC, potentially alleviating challenges in manufacturability or scalability. Similarly, a slow clock-speed may be compensated by advantages that translate into higher fidelity, since a quantum computer can then produce the correct answer to a given problem with a higher probability, requiring fewer trials to succeed.

As quantum computing technologies mature, many researchers have begun to explore whether quantum computational advantage might be obtainable *without* quantum error correction. A minimal demonstration of the viability of this program was provided in the pioneering work of Ref. [2] on random circuit sampling (RCS), in which a quantum computer performed a (contrived) task that appeared to be infeasible to simulate on even the most powerful classical computers. It is interesting to note that the same desirable qualities for achieving large-scale error-corrected quantum computing — speed, connectivity, fidelity, and size — all play a fundamental role in determining the relative separation between the computational power of quantum computers and classical computers for RCS. For example, tensor-network methods based on compressed contraction allow classical computers to simulate quantum circuits with imperfect fidelity [3, 4], with the fidelities achievable in simulation determined primarily by the connectivity of the circuit (higher connectivity generally leading to lower effective fidelity given fixed classical resources). Therefore, in-

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creasing a quantum computer's connectivity, fidelity, or both can strongly frustrate such simulation methods.

In this paper, we describe upgrades to Quantinuum's H2 trapped-ion QCCD quantum computer that enable it to operate with up to 56 qubits while maintaining arbitrary connectivity and improving upon the high twoqubit gate fidelities reported in Ref. [6] (Sec. II). As a test of the H2 quantum computer's capabilities, we implement RCS in randomly assigned geometries. In Sec. III, we show that the arbitrary connectivity of H2 enables the execution of flexibly programmed circuits that appear to be extremely challenging to simulate classically even at relatively low circuit depths. In Sec. IV, we show that the combination of low depth requirements (afforded by arbitrary connectivity) together with the high gate fidelities achieved on the H2 quantum computer enable sampling from classically-challenging circuits in an unprecedented range of fidelity: Circuits deep enough to saturate the cost of classical simulation by exact tensornetwork contraction (assuming no memory constraints) can be executed without a single error about 35% of the time. Historically, the most significant loophole in the claim that RCS is classically hard in practice stems from the low circuit fidelities that have been achievable for circuits deep enough to become hard to simulate classically. The high fidelities achieved in this work appear to firmly close this loophole. Unlike previous RCS demonstrations, in which circuits have been carefully defined in reference to the most performant achievable gates, our circuits are comprised of natural perfect entanglers (equivalent to control-Z gates up to single-qubit rotations) and Haar-random single-qubit gates. All circuits are run "full stack" with the default settings that would be applied to jobs submitted by any user of H2, without any special purpose compilation or calibration. Our primary conclusion is that even with 56 qubits, the computational power of H2 for RCS is strongly limited by qubit number and not fidelity or clock speed, with the implication that the separation of computational power between QCCD-based trapped-ion quantum computers and classical computers will continue to grow very rapidly as the qubit number continues to be scaled up.

II. THE H2 QUANTUM COMPUTER

The H2-series quantum computers are built around a race track-shaped surface-electrode trap, illustrated in Fig. 1. Similar to previous work [6], each qubit is encoded in the ${}^{2}S_{1/2} | F = 0(1), m_{F} = 0 \rangle \equiv |0(1)\rangle$ hyperfine states of a 171 Yb⁺ ion, and we use 138 Ba⁺ ions as sympathetic coolants. Each of the colored circles in Fig. 1 represents a Yb ion (qubit), which is stored in a two-ion crystal with a single Ba coolant ion (the crystal order alternating between Yb-Ba and Ba-Yb around the track). Prior to application of a two-qubit gate or the physical swapping of two qubits, the two crystals associated with those two qubits are merged into a single Yb-Ba-Ba-Yb

or Ba-Yb-Yb-Ba crystal (with gating only performed in the former configuration). An initial 32-qubit configuration of H2 was described in detail in Ref. [6], though the trap described in that work was designed to eventually support larger qubit numbers. Here we describe the system performance following a recent operational upgrade to 56 qubits. The primary technical challenge in scaling from N = 32 to N = 56 was the development of transport waveforms for a larger number of potential wells. The new waveforms use the same basic primitives to rearrange qubits — linear transport, split/combine, and physical swap, see Fig. 1(e) — but the exact trajectories and spacing between potential wells have been reconfigured.

All quantum operations including state preparation and measurement (SPAM), single-qubit (1Q) gates, and two-qubit (2Q) gates are performed as described in Ref. [6] using only the bottom 4 (out of 8 possible) gate zones. A summary of benchmarking results for these primitive operations is given in Table I. One-qubit and two-qubit randomized benchmarking (1Q and 2Q RB) were performed with standard Clifford randomizations. Transport 1Q RB was performed with all 56 available qubits in a similar method described in Ref. [6], and is intended to capture the combined effects of memory errors and 1Q gate errors (i.e. all errors not originating from the 2Q gates) on the circuits considered in this paper.

We emphasize that the fidelity of primitive operations (gates, state preparation, and measurement) has not degraded relative to the initial N = 32 configuration of H2. In fact, various technical improvements including reductions in laser phase noise have decreased the average error of our native perfect entangler from $\epsilon_{2Q} = 1.83(5) \times 10^{-3}$ measured in Ref. [6] to $\epsilon_{2Q} = 1.57(5) \times 10^{-3}$ reported in Tab. I and used to estimate circuit fidelities in Sec. IV. The primary detrimental impact of loading more qubits into the trap is that the average time to execute a layer of N/2 randomly selected gate pairs (depth-1 time) increased from 53 ms at N = 32 to 80 ms at N = 56, with an associated increase of the memory error per qubit per layer from 2.2(3) × 10⁻⁴ at N = 32 to 4.0(4) × 10⁻⁴ at N = 56. After taking the data for Fig. 9, additional improvements including the implementation of more efficient laser cooling methods have reduced the depth-1 time to around 70 ms, while also lowering the 2Q gate error rate further to the $\epsilon_{2Q} = 1.28(8) \times 10^{-3}$ reported in Ref. [7]. We expect that increasing the detuning of the 2Q gate lasers (to operate at the same detuning used currently by the H1 quantum computer) will lead to about another 4×10^{-4} improvement, bringing the 2Q gate fidelities on H2 up to the 99.9% level achieved on H1 [7].

III. THE DIFFICULTY OF RANDOM CIRCUIT SAMPLING

Random circuit sampling (RCS) [8], as first envisioned and carried out on a superconducting quantum computer



FIG. 1. Demonstration of how a densely-gated circuit (N/2 2Q gates per layer) with arbitrary connectivity is executed on the H2 quantum computer. (a) The first layer is executed by assigning each qubit to a unique ¹⁷¹Yb⁺ ion (colored disk) such that gated qubits are co-located; each ion is labeled by a unique color, and the black lines connecting neighbors indicate that the associated qubits will be gated. Since H2 is currently configured with 4 active gate zones, the two-qubit (2Q) gates are executed in 7 batches of 4 parallel gates. (b) The first batch of four gates [highlighted in magenta in (a)] are executed in parallel in the bottom row of gate zones, and qubits are then shuffled around the trap in a "rolodex" fashion until all gates (including 1Q gates) in the first layer have been applied. (c) The next layer of gates can act on arbitrary pairs. (d) An automated compilation step decides where to locate qubits in the trap (placement) and how to get them there (routing), resulting in a new assignment of qubit positions that ensures all pairs of qubits to be gated in this layer are once again co-located. Given the placement determined in (d), sequences of voltages are applied to the trap electrodes that, via a combination of the split/combine, shift, and swap operations shown in (e) achieve the desired ion placement for this layer of gates shown in (f). The gates can once again be executed in a rolodex fashion, and this entire process is repeated until all layers of gates have been applied. Note that additional coolant ions are omitted in these illustrations; as described in Ref. [5, 6] each ¹⁷¹Yb⁺ qubit ion is paired with a ¹³⁸Ba⁺ coolant ion.

Label	Test	Value $(\times 10^{-4})$
$\epsilon_{1\mathrm{Q}}$ $\epsilon_{2\mathrm{Q}}$ ϵ_{mem} p_{SPAM}	1Q RB 2Q RB Transport 1Q RB SPAM	$\begin{array}{c} 0.29(4) \\ 15.7(5) \\ 4.0(4) \\ 14.7(9) \end{array}$

TABLE I. Average component benchmarking results for the tests outlined in Sec. III of Ref. [6]. All quantities labeled by subscripted ϵ are average infidelities. The value reported for p_{SPAM} is the mean of the probabilities p(1|0) and p(0|1), where p(b|a) is the probability to measure b after preparing a qubit in state a.

in Ref. [2], is a computational task designed to highlight the difficulty of using a classical computer to simulate a quantum computer. There are four primary factors determining the separation between classical and quantum run-times for RCS: the quantum computer's speed, size (number of qubits), gate fidelity, and connectivity. We note that until very recently [9], existing work on random circuit sampling has been heavily focused on circuits with 2D connectivity [2, 10–12]. The primary reason is that connectivity beyond 2D is technologically difficult to achieve in quantum computing platforms with fixed qubit locations, and to date 2D arrays of superconducting qubits are the only quantum computing architecture to have reached the system sizes and gate fidelities required to make RCS classically hard in practice (though significant progress towards executing computationally complex circuits with neutral atom arrays has recently been made [9]). Below, we will show how improved connectivity specifically leads to dramatically more favorable scaling between quantum and classical run times for RCS.

The task of RCS begins with a description of a random quantum circuit C, which we take to act on N qubits with d dense layers of 2Q gates ("dense" meaning that there are N/2 2Q gates per layer). The quantum state $|\Psi\rangle$ obtained by applying C to the input state $|0\rangle^{\otimes N}$ induces a probability distribution over output bitstrings x_j given by $P(x_j) = |\langle x_j | \Psi \rangle|^2$. Informally, the goal of RCS is simply to sample bitstrings from a distribution that is suitably close to the ideal distribution P. Since RCS refers only to producing samples, and not the actual state $|\Psi\rangle$, it can equally well be performed on a classical or quantum computer, making it a natural computational task for which their respective powers can be compared.

We first consider performing RCS with a quantum computer, which we assume can implement 2Q gates with an error probability (process infidelity) ε . For simplicity, we assume in this preliminary discussion that all operations other than 2Q gates are perfect, though later calculations will use a more sophisticated model that in-

corporates various measured sources of error into an *effective* per-2Q gate process infidelity, as well as SPAM errors. The quantum computer executes the circuit M times and provides a list of M samples (length-N bit strings) x_1, x_2, \ldots, x_M , each drawn from the probability distribution \mathscr{P} induced by the *noisy* circuit. One potential measure for the closeness of \mathscr{P} to P — originally proposed in Ref. [2] but widely adopted in experimental RCS efforts [9–12] since then — is a suitably scaled and shifted version of the linear cross-entropy

$$F_{\rm XEB} = 2^N \left(\sum_x \mathscr{P}(x) P(x) \right) - 1 \tag{1}$$

$$\approx 2^N \left(\frac{1}{M} \sum_j P(x_j)\right) - 1,$$
 (2)

where the second line is an estimator of the first using the bitstrings sampled from \mathscr{P} . For sufficiently deep random quantum circuits, the probabilities P are themselves expected to be distributed according to the Porter-Thomas distribution. As a consequence, noiseless sampling [replacing $\mathscr{P} \to P$ in Eq. (1)] can readily be shown to result in $F_{\text{XEB}} = 1$. On the other hand, if the circuit is so noisy that it outputs the completely mixed state, then the bitstrings are sampled uniformly at random $(\mathscr{P}(x) = 1/2^N)$, and Eq. (1) yields $F_{\text{XEB}} = 0$.

While producing samples with a large F_{XEB} does not necessarily imply faithful sampling, the above two limits suggest that F_{XEB} might be a reasonable estimator of the fidelity F of the state output by the circuit; if so, then sampling from a quantum computer with a high $F_{\rm XEB}$ can serve as evidence of faithful RCS. A more careful justification for $F_{\text{XEB}} \approx F$ can be made by treating the noise on the 2Q gates as stochastic Pauli error channels, such that with probability ε each 2Q gate is accompanied by a non-identity Pauli error. For circuits that generate highly entangled states one expects the presence of even a single Pauli error to cause both F and F_{XEB} to nearly vanish, in which case both must be approximately equal to the probability that no error has occurred in the entire circuit (up to small expected boundary effects [13], see Appendix A_2),

$$F \approx F_{\text{XEB}} \approx (1 - \varepsilon)^{Nd/2}.$$
 (3)

Early work on RCS generally assumed that any classical algorithm capable of producing samples with a nonzero $F_{\rm XEB}$ must essentially achieve a simulation of the quantum circuit in question with fidelity comparable to $F_{\rm XEB}$. Since simulating complex circuits with high fidelity is believed to be classically hard, this assumption makes it natural to *define* the task of RCS as simply the generation of samples with a particular non-zero value of $F_{\rm XEB}$. However, this definition has several potential drawbacks. First and foremost, it is susceptible to the possibility that while faithfully sampling a circuit's output distribution is classically hard [14–17], producing large $F_{\rm XEB}$ values without faithful sampling is not. Moreover, even if large $F_{\rm XEB}$ does indicate faithful sampling, computing F_{XEB} from quantum data in order to validate that RCS was performed is necessarily hard in the desired regime of quantum advantage because computing the probabilities $P(x_j)$ of observed bitstrings must be performed classically, and is at least as hard as classically sampling from the probability distribution P.

Several recent works have scrutinized the relationship between $F_{\rm XEB}$ and the output state fidelity F in considerable detail [12, 13, 18]. Part of the conclusion of these works is that F_{XEB} is a good estimator of fidelity in the so-called "weak noise" regime, in which the probability of error per layer, $\varepsilon N/2$, is sufficiently small, and RCS experiments in the weak noise regime were carried out in Ref. [12]. When the noise rate exceeds a threshold value that depends on the choice of quantum gates and circuit geometry, there is a sharp phase transition into a "strong-noise" regime in which noise prevents quantum correlations from spreading across the system, and $F_{\rm XEB}$ can dramatically overestimate fidelity. The analysis of Ref. [18] for circuits with random geometries and the same gate set considered here, along with noisy simulations using a detailed error model for our machine, suggests that our experiments are very deeply in the "weak-noise" limit. Therefore, as long as circuits are deep enough for the output probabilities to be Porter-Thomas distributed, Eq. (3) is expected to hold (see Appendix A2 for further justification of this claim).

Reference [13] also points out that in a more adversarial setting, in which noise is tailored to make circuits easier to simulate by essentially removing gates in order to cut qubits into disconnected subsystems, particularly large discrepancies between F_{XEB} and F can be achieved in the limit that both are small. These results suggest a route to classically sampling with F_{XEB} values that are anomalously large compared to the achievable simulation fidelity, calling into question the use of achieving high linear cross-entropy scores *per se* as the definition of RCS. The circuits executed on H2 and reported in this paper should be robust against such classical methods due to a combination of their high fidelity (which allows very few gates to be removed) and their high connectivity (which ensures that simulation remains difficult unless a large number of gates are removed). In particular, our circuits have their gates drawn from the edges of graphs with good edge-expansion properties (see Appendix A5), which ultimately ensures that it is not possible to disconnect the system into two equally sized subregions without cutting an extensive number of gates, even at constant depth.

In light of the discussion above, in this work we primarily focus on providing direct evidence for the ability of the H2 quantum computer to sample with high fidelity from circuits that are difficult to classically simulate. Nevertheless, we do compute F_{XEB} for system sizes that we are able to $(N \leq 40)$, and confirm that it agrees well with other fidelity estimates. We also report samples from circuits for which we are unable (due to the severe classical difficulty of simulating the circuits) to compute F_{XEB} . We are generally unaware of *any* classical methods to produce F_{XEB} numbers comparable to what we expect from these circuits without performing essentially exact numerical simulations of the circuit (up to the modest loss in fidelity observed experimentally, see Sec. IV). While the above statement certainly warrants further scrutiny, we take this assumption as motivation to focus primarily on the difficulty of exact tensor network contraction in the remainder of this work. However, in Sec. III C we also analyze the performance of tensor-network-based approximate simulation techniques, and show that the random geometries explored here significantly increase (relative to local geometries) the classical resource requirements to achieve a given quality of approximation.

A. Circuit geometry and the cost of exact tensor-network contraction

The most efficient known general-purpose classical method to simulate quantum circuits is to represent the probability of an output bit string as a tensor network (TN) and perform exact contraction of that network. Together with rejection sampling or other related methods, such calculations enable classical RCS at a cost lowerbounded by the cost of computing one such probability. Actually contracting the TN associated to a single probability incurs a cost that can be *highly* dependent on the order in which the contraction of tensors is performed. For example, while there is always an ordering that leads to a time-like progression of the full statevector, with a computational cost that scales as 2^N , circuits of low depth and/or low-connectivity will generally admit contraction orders with much lower cost. Therefore, to assign a cost to the contraction of a given TN it is critical to minimize the contraction cost over all possible contraction orders. While it may be computationally hard to determine the optimal contraction order in general [19], many good heuristic methods have been developed in recent years. The contraction costs reported in this manuscript are obtained using cotengra [20], a Python library that supports a variety of performant heuristic contraction order optimizers and hyperparameter optimization strategies to tune those optimizers. For the results discussed in this section contraction order is optimized by targeting the minimization of floating-point operations (FLOPs) assuming no memory constraints. Since we have not performed exhaustive searches for FLOPsoptimized contraction orderings, all reported costs are, strictly speaking, only upper bounds on the true contraction cost. However, it is also important to note that the assumption of unconstrained memory can cause one to seriously *underestimate* the cost of contraction in a more realistic memory-constrained setting. The deepest 56qubit circuits run in this paper are likely *much* harder to contract in practice than the FLOPs requirements computed in this section would suggest. In Sec. III B we investigate the complexity of memory-constrained TN con5



FIG. 2. The circuits considered in this paper have geometries induced by random regular graphs. For a depth-*d* circuit on N qubits, denoted $C_{d,N}$, we sample a random *d*-regular graph on N nodes, denoted $\mathcal{G}_{d,N}$ (the example shown above is for a depth-3 circuit on 6 qubits). To arrive at a circuit we associate each vertex of \mathcal{G} with a qubit in C, and then assign \mathcal{G} an edgecoloring. Each color is associated with a layer of 2Q gates in C, with each edge of that color corresponding to a 2Q gate in that layer. Adjacent 2Q layers are separated by a layer of Haar-random 1Q gates on each qubit (with a single layer of 1Q gates immediately after state preparation and another immediately before measurement).

traction for our circuits in more detail, and show that it continues to grow extremely quickly with depth after the measure of complexity [see Eq. (6)] plotted in Fig. 3(c) saturates.

A convenient way to parameterize the contraction cost of the TN corresponding to a quantum circuit is to take the base-2 logarithm of the required FLOPs per gate for performing the contraction [21],

$$\mathcal{N}_{d,N} = \log_2\left(\frac{\text{cost in FLOPs}}{Nd/2}\right).$$
 (4)

Because the cost per gate (in FLOPs) of brute-force statevector simulation of \mathscr{N} qubits scales as $2^{\mathscr{N}}$, \mathscr{N} can be interpreted as an *effective qubit number* in the following sense: A depth d circuit C with cost $\mathscr{N}_{d,N}$ may act on $N > \mathscr{N}_{d,N}$ qubits, but it is only (roughly) as difficult to simulate as the worst-case hardness of simulating $\mathscr{N}_{d,N}$ qubits. At any fixed depth d, a circuit that is spatially local in D-dimensions should have an effective qubit number scaling (asymptotically as $N \to \infty$) as the area of a minimal bisecting surface,

$$\mathcal{N}_{d,N} \sim d \times N^{(D-1)/D}.$$
 (5)

This result is perhaps most recognizable in dimensions D = 1, 2, with the implication that the simulation cost of finite depth circuits is asymptotically independent of N for 1D circuits, and exponential in \sqrt{N} for 2D circuits. It is also convenient to define a normalized effective qubit number

$$\mathscr{C}_{d,N} \equiv \mathscr{N}_{d,N}/N \sim \frac{d}{N^{1/D}},\tag{6}$$



FIG. 3. Comparison of complexity density $\mathscr{C}_{d,N}$ for circuits with random geometries (RG) and 2D geometries. Figures (a) and (b) show the gating pattern for a depth-4 graph on 56 qubits given random and 2D geometries, respectively. At each value (N, d), an N-node graph is assigned a coloring using either d colors (RG) or 4 colors (2D). Each circuit is comprised of layers of $U_{ZZ}(\pi/2)$ gates separated by layers of random SU(2) gates on each qubit, with the U_{ZZ} gates applied to each pair of qubits whose associated vertices are joined by an edge of one color. In (a) each layer corresponds to a unique color, while in (b) the 4 colors are repeated cyclically until the desired depth is reached. Figures (c) and (d) show estimates of $\mathscr{C}_{d,N}$ for such RG and 2D circuits, respectively. While the complexity density for RG circuits is constant for $N \to \infty$ at fixed depth [evidenced by the horizontal contours in (c)], the log-log plot in the inset of (d) shows that $d \sim \sqrt{N}$ is required to maintain fixed complexity density in 2D. The white arrows in (c,d) highlight how far the depth needs to be increased at N = 56 before the complexity density saturates (i.e. the TN contraction cost becomes roughly equivalent to the cost of doing brute-force N = 56 state vector simulation).

which we refer to as the *complexity density* of the circuit; it quantifies what fraction of the qubits contribute to the worst-case complexity of simulation. Equation (6) implies that the asymptotic complexity density,

$$\mathscr{C}_d \equiv \lim_{N \to \infty} \mathscr{C}_{d,N},\tag{7}$$

vanishes at any fixed depth for spatially local circuits, and therefore such circuits must be made deeper as they are made wider $(d \sim N \text{ in 1D or } d \sim \sqrt{N} \text{ in 2D})$ in order for the contribution of each qubit to the complexity of simulation to not vanish. To understand the behavior of very highly connected circuits, it is suggestive to consider the limit $D \to \infty$ in Eq. (6); evidently the asymptotic complexity density will either be constant or decreasing more slowly with N than any power-law. In this work, we will consider a family of highly connected geometries for which \mathscr{C}_d is provably bounded below by a constant (see Appendix A5).

Given the flexibility of H2, we do not focus on a specific high-dimensional geometry but instead consider highly connected circuits with random geometries, a small example of which is shown in Fig. 2 (a detailed discussion of random-geometry circuit generation can be found in Appendix A4). A random-geometry (RG) circuit $C_{d,N}$ of depth d on N qubits is generated by first selecting a random d-regular graph $\mathcal{G}_{d,N}$ with N nodes (d-regular meaning that exactly d edges impinge on each node). Each node of $\mathcal{G}_{d,N}$ is assigned to a qubit in $C_{d,N}$, and each edge to a 2Q gate. The native 2Q gate of all Quantinuum H-series hardware is the parameterized entangler $U_{ZZ}(\theta) = \exp(-i(\theta/2)Z \otimes Z)$, and each of the $(N \times d/2)$ 2Q gates is chosen to be the perfect entangler $U_{ZZ}(\pi/2)$. The 2Q gates are then sorted into d layers with N/2 gates per layer by finding a proper edge coloring of $\mathcal{G}_{d,N}$ and then assigning one of the d colors to each of the d layers of the circuit. Edges of a given color then have their associated 2Q gates executed in the layer to which that color is assigned. A layer of Haar-random 1Q gates on every qubit is inserted immediately after qubit initialization, immediately before measurement, and between every layer of 2Q gates (for a total of d + 1 1Q layers).

To highlight the impact of connectivity on contraction complexity, in Fig. 3 we compare the complexity density of RG circuits to that of 2D circuits. The 2D circuits are similar in structure to the RG circuits described above, except that the gated pairs are drawn as edges of a 2D square lattice, as in Fig. 3(b). All gates corresponding to edges of a given color can be applied in a single layer, and for circuits with d > 4 layers we simply proceed cyclically through the color list until the desired depth is reached. To minimize contraction cost fluctuations due to boundary effects, we sample 10 2D grids at each Nand d, where each grid is obtained by starting with a nominal square lattice with a vertex centered at the origin, applying a random offset and rotation to the lattice, and then selecting the N vertices with smallest Euclidean distance from the origin. The 2D circuits are slightly less densely gated than the RG circuits (which always have exactly N/2 gates per layer) because qubits at the edges of the 2D lattice are not gated in each layer. To make a fair comparison between RG and 2D circuits, we associate an effective circuit depth $d_{\text{eff}} = n_{2Q}/(N/2)$ to each circuit, with n_{2Q} the number of 2Q gates in the circuit (note that $d_{\text{eff}} = d$ for the densely-gated RG circuits). Comparisons at fixed d_{eff} and N then always amount to comparisons at a fixed total number of 2Q gates. It is also important to note that for this comparison, we have chosen the Quantinuum native $U_{ZZ}(\pi/2)$ gate as the 2Q gate. It is well known that iSWAP-like gates (gates with maximum entropy of their singular value decomposition) lead to relatively harder to simulate 2D circuits than $U_{\rm ZZ}(\pi/2)$ when compared at fixed depth; the contraction cost estimates reported here for 2D circuits should not be conflated with direct cost estimates of circuits run in specific experiments on superconducting qubits, which will generally be higher for a given (N, d) given the use of rank-4 entangling gates. Nevertheless, the scaling arguments made here apply equally well regardless of the 2Q gate choice.

As discussed above, constant complexity density is maintained by scaling $d \sim \sqrt{N}$ in 2D [see the inset of Fig. 3(d)]. In contrast, RG circuits empirically achieve fixed complexity density at constant depth as $N \to \infty$, evidenced by the flat contours in Fig. 3(c). The constant asymptotic complexity density observed in Fig. 3(c) is proven in the appendices, and is a consequence of the gate pairs being chosen in correspondence with the edges of graphs with good asymptotic expansion properties. The white-dashed arrows in Fig. 3 correspond to the circuits achievable in the current 56-qubit configuration of H2, and at this system size the depth at which $\mathcal{C}_{d,56}$ saturates to near unity (i.e. where the contraction cost saturates to the statevector simulation cost of 56 qubits) is roughly half as large $(d \approx 12)$ for RG circuits as for 2D circuits $(d \approx 22).$

B. Exact contraction cost with memory constraints

Optimization of TN contraction solely targeting FLOP minimization can result in contraction orders that produce large intermediate tensors; the FLOP cost of a TN



FIG. 4. The impact of constraining memory on cost for TN contraction of a single amplitude for random quantum circuits with N = 56. (a) FLOP cost of unconstrained optimized contraction paths compared with those sliced to $W=2^{30}$ as a function of circuit depth, d. The cost of statevector simulation is marked for reference. (b) Size of the largest intermediate tensor, or 'contraction width', W, as a function of circuit depth. The lines represent the median behavior across 20 circuit instances, with the bands showing the min/max range.

contraction is immaterial if those intermediate tensors cannot fit within available memory. While utilizing distributed storage for contractions is a theoretical possibility up to a point, in practice, all large scale brute-force TN simulations of random quantum circuits [22–24] have favored a technique called *slicing* [25, 26] that instead breaks the computation into many independent tasks, each able to fit onto a single GPU. It is therefore natural to optimize the FLOP cost of sliced contraction subject to a constraint on the memory footprint of each individual slice. The potentially enormous reduction in memory footprint is not always free however, and at some point redundantly repeated operations introduce significant overhead. Below, we will compare the memoryunconstrained and sliced cost for exact computation of a single amplitude ('strong simulation') of the random quantum circuits considered here, which serves both as a baseline for various tasks such as sampling and XEB verification, and a useful comparison point to other circuits. We employ hyper-graph partitioning [20, 27] with simulated annealing refinement [23] to find highly optimized TN contraction paths, and in the sliced case enforce a maximum tensor size, or 'width' $W = 2^{30}$, appropriate for the current generation of GPUs with 40-80GB of memory.

In Fig. 4(a,b) we plot the contraction cost in FLOPs (assuming complex tensors) and the contraction width

as a function of circuit depth, d, averaged over 20 circuit instances at N = 56. We also show the reference FLOPs of statevector contraction and identify three distinct regions. First a 'shallow' region where both the cost and width increase exponentially but are still far below the statevector cost and no slicing is needed. Next, an 'intermediate' regime where even though the slicing reduces W by a factor of up to $2^{26} \sim 64$ million, it introduces no significant overhead. Finally, a 'deep' regime where the unconstrained FLOPs and width converge with statevector, but the cost of the sliced contraction continues to grow exponentially.

At the intermediate to deep transition point around d = 12, where slicing overhead starts to emerge, the FLOP cost of $\sim 10^{20}$ is already very significant, although certainly within reach of the largest super-computers which can achieve $\sim 10^{18}$ FLOPs per second [28]. However the median sliced cost continues to exponentially grow to $\sim 10^{30}$ as the depth increases to d = 20, putting the computation well out of reach. We note that while improved techniques (that make use of extensive caching for example) might bring this cost down somewhat, no such method is expected to fully remove the exponential cost of constraining $W \ll 2^N$ for deep circuits.

We also emphasize that these costs are meant primarily to situate the relative classical hardness of different depths with respect to other circuits. As discussed in Sec. III D, quantum RCS efforts generally produce S samples from C different circuits (for a total of $M = S \times C$ samples) such that the *expected* value of F_{XEB} averaged across all samples could in principle be distinguished from zero with high statistical confidence (putting aside the question of how hard the verification would be). To actually simulate the RCS experiments performed in this paper or to verify F_{XEB} of the samples generated by H2, one would want to perform at least S such amplitude contractions for each of the C circuits. While recent advances have shown that 'multi-contraction' for a single circuit can be performed with cost sublinear in S [22– 24], having to draw many samples still presents a significant computational increase. Moreover, in all RCS data that we report [29] we use a relatively small number of shots per circuit (S = 20), so the sublinearity of such methods provides only a marginal benefit. We also note that when targeting $F_{\text{XEB}} < 1$ in classical RCS, a generic speedup of $1/F_{\text{XEB}}$ is available to brute-force TN methods [30]. Given the large fidelity values expected even for the deepest circuits implemented in this paper $(F \ge 0.1 \text{ at } d = 24, \text{ see Sec. IV})$, exploitation of hardware imperfections to perform classical RCS of our circuits at suitably reduced fidelity appears to offer no significant speedup.

C. The cost of approximate tensor network simulations

One promising method for approximately simulating quantum circuits is to utilize a tensor-network-based ansatz suitable for capturing states with limited bipartite entanglement. At sufficiently early times, when bipartite entanglement is limited, this method can be exact even for system sizes well beyond the reach of full statevector simulation. However, as the quantum state progresses through the circuit and becomes more entangled, it eventually needs to be compressed to maintain an ansatz constrained by available resources (in both memory and run time). This compression inevitably causes the state to lose fidelity with respect to the exact state, reminiscent of the way gate errors in a noisy quantum circuit cause a state to lose fidelity as the depth of a quantum circuit increases. The less noisy a quantum computer's gates are, and the more entanglement-per-gate that computer can generate, the more difficult it becomes for such methods to compete with the physically achieved fidelities for highly-entangled states.

In Refs. [3, 4], the authors have argued that in the case of a matrix-product-state (MPS) ansatz and a random circuit, the overall fidelity $F_{\rm MPS}$ of the calculation is well approximated by simply accumulating the loss of fidelity in every compression step, and is therefore readily accessible during the calculation despite the unavailability (in general) of the exact state. From the estimated simulation fidelity one can ascribe an error per 2Q gate ε_{MPS} via the relation $F_{\text{MPS}} = (1 - \varepsilon_{\text{MPS}})^{(\# \text{ of } 2Q \text{ gates})}$, which can then be compared to the effective error per 2Q gate on quantum hardware, ε . Assuming that fidelity is well approximated by F_{XEB} for both the data output by a quantum computer and for this classical simulation method [31], quantum advantage in cross-entropy benchmarking is only possible if feasible classical resources cannot achieve $\varepsilon_{\text{MPS}} \lesssim \varepsilon$. Below we will show that the high gate fidelities and connectivity of H2 make simulations based on MPS extremely challenging, and likely infeasible at the scale and fidelity of the circuits run in this work. It would be interesting to investigate to what extent approximate simulations could be improved by using a more general TN ansatz than the MPS considered here. However, fast (with circuit depth) suppression of *any* low-entanglement partitions is guaranteed by the way we construct our circuits. Ultimately, H2 can produce states that are near-maximally entangled with respect to all possible partitions while maintaining high state fidelities, and sampling from such states should pose substantial challenges for existing compression-based TN methods.

All MPS results reported in this section were obtained with a density-matrix renormalization group (DMRG) algorithm similar to that described in Ref. [4]. In particular, we approximate the amplitude of a particular output bit string of a circuit using a closed-simulation approach, e.g. we evolve one MPS forward from the initial bit string to the middle of the circuit, evolve another backward from the final bit string to the middle circuit, and then compute their overlap. We only simulate depth-20 random circuits, and use intermediate MPS results after only d/2 < 10 forward and backward layers to estimate the achievable fidelity for circuits of all depths d < 20. Given the extremely non-local geometry of our circuits, the use of a blocked MPS (in which many qubits are grouped together into a single tensor) can substantially reduce the number of long-range (inter-block) gates applied during the time-evolution if the blocks are chosen in reference to the specific random geometry in question. We explored a variety of blocking strategies using b blocks of s = 56/b qubits per block (denoted $b \times [s]$), in each case making an assignment of qubits into blocks on a circuit-by-circuit basis by attempting to minimize the number of inter-block gates using the open source hypergraph partitioning package KaHyPar [32, 33].

Figure 5(a) shows how the error per gate grows as a function of circuit depth for both 2D (black curves) and RG (magenta curve) circuits and a variety of 1Q and 2Q gate sets. The label "fSIM" (" $\pi/2$ ") denotes the 2Q (1Q) gate set of Ref. [2], while " U_{ZZ} " ("Haar") denotes the 2Q (1Q) gate set used for the circuits run on H2. For all 2D simulations we used a $7 \times [8]$ blocking strategy on a grid similar to Google's Sycamore chip (though with a slightly different aspect ratio of 7 columns and 8 rows to accommodate 56 qubits, making each column an MPS tensor), and chose the same gating pattern as that used for the "quantum supremacy" circuits in Ref. [2]. For consistency the RG circuit results are also plotted with a $7 \times [8]$ blocking strategy, though we show in Fig. 6 that results for random circuits are only weakly dependent on blocking strategy. Comparing the solid black and magenta curves, one can see that with the same gate sets RG circuits generate bipartite entanglement (heralded by the growing error rate at fixed bond dimension) much faster than 2D circuits. While utilizing 1Q and 2Q gates fine-tuned to generate maximum entanglement also can hinder the performance of DMRG in 2D, overall the impact of geometry is more severe. We note that the circuits run here could be made to entangle marginally faster by utilizing the $\pi/2$ -labeled gate set in Fig. 5, see also the discussion in Appendix A9. On the other hand, the 2Q fSIM gate utilized in Ref. [2] does not make RG circuits harder to simulate because it can be decomposed as SWAP $\times U_{ZZ}(\theta)$; all SWAP gates in a given layer can be compiled into permutations of the qubit labels in future layers, and results in a translation between different RG circuits in the same circuit ensemble considered. Figure 5(b) shows how the error per gate at depth 20 decreases when increasing the bond-dimension χ of the MPS, which controls how much entanglement the MPS can capture. From a linear fit to the largest two bond dimensions ($\chi = 128$ and $\chi = 256$), one can see that by depth 20 the random circuits appear to require close to the maximum possible bond dimension of $2^{N/2}$ to achieve an error per gate comparable to the ex-



FIG. 5. (a) Achievable error per gate $\varepsilon_{\rm MPS}$ as a function of circuit depth using DMRG for circuits with 2D and random geometries and a variety of 1Q and 2Q gate sets. All curves use a bond dimension $\chi = 256$, and shaded regions show standard deviation of the error per gate across 100 (20) circuit randomizations for random (2D) circuits. (b) Error per gate at depth 20 as a function of bond dimension. Linear extrapolation of $\varepsilon_{\rm MPS}$ to the experimental value of $\varepsilon \approx 3.2 \times 10^{-3}$ (dotted horizontal line in this figure, see Sec. IV) from the two largest bond dimensions suggests that by depth 20, DMRG cannot simulate random geometry circuits at the fidelities achieved on H2 without employing an essentially exact representation of the full statevector (MPS bond-dimension $\chi = 2^{N/2=28}$, green vertical line).

periment $[\varepsilon(N = 56) \approx 3.2 \times 10^{-3}$, black dotted line], at which point the MPS ansatz becomes exact.

In Fig. 6, we compare the scaling of ε_{MPS} for RG circuits as a function of total computational cost using various blocking choices. Various shades of pink in Fig. 6 correspond to blocking choices $4 \times [14]$, $7 \times [8]$, $14 \times [4]$, $28 \times [2]$, and $56 \times [1]$ (ordered from light to dark). While the blocking choice significantly impacts the computational cost at fixed bond dimension, overall we find that different blocking choices are all roughly comparable from the standpoint of achievable ε_{MPS} at fixed computational cost. We also plot ε_{MPS} for 2D circuits of this geometry and using the same 1Q and 2Q gate set modifications as in Fig. 5. Once again, while the use of gate sets tailored to maximize the growth of entanglement can substantially increase the error per gate at fixed cost in



FIG. 6. Error per gate ($\varepsilon_{\rm MPS}$) versus computational cost (in FLOPs) for both 2D and RG circuits. The results for RG (2D) circuits are again averaged over 100 (20) random circuits. All 2D circuits employ a 7 × [8] blocking strategy, while a variety of blocking strategies (each a different shade of pink, see main text) are attempted for the RG circuits. Cost on the *x*-axis is approximate, and estimates the number of floating-point operations required for DMRG using various block sizes as the MPS bond dimension is increased (including the cost of applying all gates to the MPS and all MPS overlap calculations encountered in DMRG, but not the cost of QR decompositions).

2D, the impact of random geometry on the cost to achieve a fixed error-per gate is more severe.

D. Time requirements for verifiable RCS

Random circuit sampling — and any related statements about its asymptotic hardness, either classical or quantum — can be formulated purely in reference to the task of drawing samples from a particular distribution. There is a related but conceptually independent question regarding the sample efficiency of *verifying* random circuit sampling (or any sampling task): How many samples must be provided to offer compelling evidence of having sampled from the claimed distribution? If closeness to the ideal distribution is judged by $F_{\rm XEB}$, then the specific question becomes: If someone claims to be able to sample from a distribution with a particular value of F_{XEB} , how many samples must they provide in order for us to be confident that they can in fact do so [34]? Since the trivial algorithm of guessing random bitstrings produces $F_{\rm XEB} \approx 0$, the experimental task of RCS has often been implicitly defined as generating sufficiently many samples such that F_{XEB} — were it ever to be computed from the provided samples — would be greater than zero with high statistical confidence.

Since the statistical uncertainty on F_{XEB} scales inversely with the square root of the number of samples



FIG. 7. Maximum effective qubit number $\mathcal{N}_{\rm max}$ achievable with 100 seconds of data as a function of the 2Q gate error rate. The black (magenta) solid curve at the bottom of each region shows results for 2D (random) geometries assuming a circuit execution time of $\tau_{\rm q} = 1$ s. Each progressively fainter line above the lowest corresponds to another orderof-magnitude reduction in the assumed circuit time $\tau_{\rm q}$, with the upmost dashed line corresponding to $\tau_{\rm q} = 1 \,\mu$ s for both geometries.

taken, the total required quantum run time of a verifiable RCS experiment must scale as

$$T_{\rm q} \sim \tau_{\rm q} / F_{\rm XEB}^2 = \tau_{\rm q} / (1 - \varepsilon)^{Nd} \approx \tau_q \times e^{\varepsilon Nd},$$
 (8)

where τ_q is the quantum run time of a single shot of one circuit. This equation makes it clear that a very fast quantum computer (small τ_q) may produce enough data to witness even small statistical deviations from complete noise/randomness ($F_{\rm XEB} \ll 1$) in a reasonable amount of time. On the other hand, increased fidelity and connectivity greatly enhance the deviations of a quantum computer's output from random, thereby reducing the amount of data required and potentially compensating for a slower clock speed. While the discussion of quantum run time for verifiable RCS may seem academic, it is important to note that a similar trade off between fidelity and clock speed can be identified in most efforts to stretch the power of noisy quantum computers via error mitigation techniques [35]. Ultimately, these methods amount to extracting a weak signal encoding the noiseless result of a calculation or simulation from a background of noise in a similar spirit to RCS. While individual circuit run times on H2 are slow compared to superconducting devices (about 1 second per sample for the circuits in this paper), the high fidelity and connectivity offset this deficit, enabling convincing RCS demonstrations with comparable run times to other state-of-the-art demonstrations.

Equation (8) implicitly establishes a region of circuit volumes in the N-d plane within which a quantum computer can extract verifiable RCS data given a fixed amount of total run time T_q ,

$$d \le d_{\max}(N) \equiv \frac{\log(T_{\rm q}/\tau_{\rm q})}{\varepsilon N}.$$
(9)

By computing $\mathcal{N}_{d,N}$ for circuits of a particular geometry and maximizing it over $d \leq d_{\max}(N)$, we can determine the maximum effective qubit number accessible to a given quantum computer in a fixed total amount of run time T_{q} , denoted $\mathcal{N}_{max}(\varepsilon, \tau_{q}, T_{q})$, which in turn determines the maximum classical difficulty of simulating the data output by such an experiment. For this purpose we compute simplified models of the contraction costs for 2D and RG circuits in order to extrapolate contraction costs beyond the range displayed in Fig. 3, with parameters fitted to the contraction cost estimates obtained from cotengra for $N \leq 110$ (see Appendix A6). From these models we can compare effective qubit numbers achievable in 2D and random geometries using the same random gate set over a broad range of assumptions about the circuit time $\tau_{\rm q}$ and the 2Q gate error rate ε , as shown in Fig. 7 for a fixed total quantum run time of $T_{\rm q}~=~100\,{\rm s}$. In this figure, the bottom boundary (darkest solid line) of each shaded region corresponds to an assumed circuit time of 1 second, and each progressively lighter line above represents a decrease of τ_q by one order of magnitude (with the top most line corresponding to a circuit time of $1 \mu s$). The fast saturation of classical simulation cost with depth for RG circuits translates into significant enhancements in the achievable effective qubit number (i.e. classical simulation costs) at fixed gate error and circuit time. We note that the estimated effective qubit numbers in Fig. 7 depend explicitly on the achievable error per gate ε . To what scale the QCCD architecture can be pushed while maintaining completely arbitrary connectivity at some fixed small ε is a technical question that will only be answered by technical progress. While it is true that at *some* system size, memory errors incurred during the transport required to implement RG circuits (which will scale with N in an architecture dependent way) will exceed the 2Q gate error rates. However, we believe the scale and current performance of H2 is far from the limits of what is achievable with current technologies, especially considering recent results on junction transport [36, 37].

IV. THE FIDELITY OF RANDOM-GEOMETRY CIRCUITS ON H2

We have carried out RCS experiments on RG circuits at a variety of qubit numbers N and depths d, and all samples obtained from these experiments are reported in Ref. [29]. A small example RCS circuit (N = 6, d = 3) is shown in Fig. 8(a). The RCS experiments were randomly interleaved with other diagnostic experiments meant to validate their fidelity. Our primary tool for fidelity estimation is a mirror-benchmarking (MB) technique similar to that described in Refs. [38, 39], which we carry out at all qubit numbers and circuit depths reported in Fig. 9. Mirror benchmarking provides a fidelity estimate for a depth-d circuit by mirroring a depth-d/2 circuit such that the output state is identical to the input state, as in Fig. 8(c). Randomized compiling [40] is used on the mirrored half of the circuit to prevent the potential cancellation of coherent errors. Bias in our SPAM fidelity is removed by preparing the initial state in a random bitstring, such that the "correct" final measurement is an unbiased combination of 0 and 1 outcomes. The fraction of samples in which the qubits all return to the expected state, referred to as the MB return probability and denoted $F_{\rm MB}$, serves as an estimate of the overall fidelity of the output state for a depth-d circuit. For all RCS circuits at $N \leq 40$ we also directly compute the linear cross-entropy $F_{\rm XEB}$ from the obtained samples, which serves as a complimentary estimate of the fidelity. For all higher qubit numbers — most notably all data at N = 56 — we still report samples from the RCS experiments in Ref. [29] but do not compute F_{XEB} . While it should be computable for N = 48 with considerable effort, and at N = 56 for the shallowest depths, it does not appear possible to compute F_{XEB} for the N = 56 circuits at $d \gtrsim 12$ with any realistic amount of classical resources (see Sec. III B).

We also employ a simple gate-counting estimate based on measured fidelities of the component operations in the circuit, referred to as the "digital error model" in Ref. [2]. The largest contribution to the overall circuit infidelity is 2Q gate errors. The 2Q gate average infidelity $\epsilon_{\rm 2Q}$ reported in Tab. I is inferred from 2Q RB experiments interleaved with the rest of the data (see Appendix A1 C). The next leading source of circuit infidelity is memory error, i.e. the cumulative effect of errors that happen to qubits when not doing 2Q gates. This memory error has several origins including reference clock and magnetic field drifts, imperfections in spatial phase tracking and other calibration errors or drifts, leakage out of the qubit manifold, and transport failures; see Ref. [6] for further discussion. Since memory error is closely related to the transport time, its magnitude varies with circuit geometry and qubit number. Therefore, to estimate the contribution of memory error we run a separate transport 1Q RB experiment at each qubit number [see Fig. 8(b), Appendix A1D and Tab. A1]. The geometry of the transport 1Q RB circuits at low depths is taken to exactly match the same circuits used in the RCS experiments. By making the replacement $U_{ZZ}(\pi/2) \rightarrow U_{ZZ}(0)$ for all 2Q gates, the transport 1Q RB circuits replicate nearly identical transport steps, cooling, 1Q gates, and overall timing as the RCS circuits without ever applying 2Q gates. In the absence of 2Q gates, the ideal circuit prepares each qubit in a known state. From the decay (with circuit depth) of the probability that each qubit ends in the correct state, we can extract an estimate of the aggregate non-2Q gate contributions to the error per qubit per layer, denoted $\epsilon_{\text{mem}}(N)$ [41].

Combining the memory error with the estimate of 2Q



FIG. 8. Illustrative examples of the circuits implemented experimentally in this paper. (a) A depth-3 RCS circuit on 6 qubits (see Fig. 2 for a description of the notation). (b) Transport 1Q RB version of the same circuit. 2Q gates with unfilled boxes denote the use of a $U_{ZZ}(0)$ gate, which induces the same transport and cooling operations as the $U_{ZZ}(\pi/2)$ but does not apply a 2Q gate. The circuit is initialized in a random bit string, in this case 011010, and the 1Q gates at the end (solid black squares) invert the cumulative action of all prior 1Q gates in order to return to this initial state, as shown in (d) for a single qubit. (c) Mirrored version of the same circuit, here initialized in the random bit string 101001. On the reversed part of the circuit all 1Q gates are inverted, $U_{ZZ}(-\pi/2)$ gates are created from $U_{ZZ}(\pi/2)$ gates by appending suitable 1Q Z rotations, and randomized compiling is used to twirl any potentially coherent errors in the 2Q gates into incoherent errors (avoiding any potential cancellation of coherent errors between the forward and backward halves of the circuit). All 1Q gates on the reverse half are then compiled down to the gates represented as hashed squares in (c), as shown in (e) for a single qubit.

gate error from randomized benchmarking, the effective process/entanglement infidelity per 2Q gate is

$$\varepsilon(N) = \frac{5}{4}\epsilon_{2Q} + 2 \times \frac{3}{2}\epsilon_{\rm mem}(N), \qquad (10)$$

where the prefactors incorporate the conversion between average and process fidelities [42] as well as the fact that there are two qubits in each 2Q gate [43]. Note that we do *not* include a contribution from ϵ_{1Q} listed in Tab. I, since 1Q gate errors are already accounted for in $\epsilon_{mem}(N)$. A reasonable model for the overall fidelity of the circuit then simply counts the number of 2Q gates and state preparation and measurement operations and takes the corresponding fidelities to the appropriate power:

$$F_{\rm GC}(N,d) = \left(1 - \varepsilon(N)\right)^{Nd/2} \left(1 - p_{\rm SPAM}\right)^N.$$
(11)

The SPAM error p_{SPAM} is measured from an independent SPAM experiment, and reported in Tab. I. As demonstrated in Appendix A2, this gate-counting model for

the circuit fidelity tends to systematically underestimate both the true circuit fidelity as well as the fidelity estimates $F_{\rm XEB}$ and $F_{\rm MB}$ provided by the linear crossentropy and the average return probability of mirror circuits, respectively. Consequently, following the analysis of Appendix A2, the effective depth in the gate-counting model is shifted by approximately 1.12 for direct comparison with $F_{\rm XEB}$ and $F_{\rm MB}$.

We report our experimental results in Fig. 9. The set of all circuits for which we report data in Fig. 9(a,b) were submitted to the H2 quantum computer in a random order so as to fairly average across any drift in computer performance, using default settings accessible to any user of the device. The set of N = 40 circuits for which we verify the linear cross-entropy F_{XEB} in Fig. 9(c) were submitted (and executed) immediately afterwards, also in a random order. In Fig. 9(a), where we expect that F_{XEB} is not computable except with substantial effort at the lowest depths, we report MB estimates of the fidelity achieved by H2 at 56 qubits on RG circuits out to

13



FIG. 9. Fidelity estimation from H2 data at a variety of qubit numbers and circuit depths. (a) $F_{\rm MB}$ (MB return probability, green) at N = 56 as a function of depth. We also plot a fidelity estimate at depth 12 (pink) inferred from the MB return probability at depth 24 from mirror circuits that were constructed from the exact depth-12 RCS circuits. The color gradient corresponds to the complexity density from Fig. 3. (b) $F_{\rm XEB}$ (linear cross-entropy, orange) and $F_{\rm MB}$ (green) as a function of qubit number N at fixed depth d = 12. (c) $F_{\rm XEB}$ (orange) and $F_{\rm MB}$ (green) as a function of depth at N = 40, the largest of the N we took data at that was classically verifiable with our computational resources. All uncertainties plotted represent 1σ confidence intervals on the data. The gray shaded regions represent 1σ confidence intervals on the gate-counting model arising from propagation of uncertainties on the component operation fidelities.

depth 20. The estimated fidelities are roughly two orders of magnitude larger than those reported in prior RCS demonstrations on classically difficult circuits [2, 10–12]. We also execute MB circuits at depth 24 that are mirrored versions of the exact depth-12 RCS circuits to provide another consistent estimate of the fidelity at depth 12 for N = 56. This procedure is similar to the one proposed in Ref. [44] but without the randomly compiled reference circuit and with SPAM errors added back in to better match expected circuit performance.

In Fig. 9(b) we show that F_{XEB} computed up to N = 40 agrees well with $F_{\rm MB}$ and the gate-counting model across a range of N at depth 12, where we expect that the cost of simulating the circuits is roughly equal to the statevector simulation cost, c.f. Sec. III A. Further verification that $F_{\rm XEB}$ is well estimated by $F_{\rm MB}$ is provided by taking data at N = 40 across a wide range of circuit depths in Fig. 9(c), and computing $F_{\rm XEB}$ from the obtained samples on the Perlmutter supercomputer. All MB and RCS experiments were executed with 50 circuit randomizations and 20 shots per randomization at each depth, with the exception of the depth-24 experiment which was executed with 50 circuit randomizations and 100 shots per randomization. All experimental data is provided at [29], including data from random circuits for which we could not compute F_{XEB} .

V. OUTLOOK

Demonstrating a convincing computational advantage of quantum computers over classical computers is widely regarded as a key milestone on the path towards broadly useful quantum computation, and much progress towards this goal has been made in recent years. From a formal point of view, one would ideally like for such a demonstration to be based around a problem for which an exponential asymptotic advantage can be claimed as the size of the problem (and the computer used to tackle it) grows. Since the original proposal for RCS as a task for demonstrating exponential quantum advantage [45], substantial progress has been made in understanding its asymptotic difficulty both with and without circuit noise. For example, compelling evidence now exists that *noiseless* RCS requires exponential (in the qubit number) run time for a classical computer [14–16].

In the absence of quantum error correction, the asymptotics of *noisy* RCS (i.e. the task of sampling from the output distribution that results from running a quantum circuit with a fixed level of noise per gate) are relevant but remain comparatively less well understood. Notable recent developments include a proof that under certain assumptions about the noise structure and circuit depth, RCS is asymptotically easy for classical computers if the error-rate per gate is held constant as the system size is scaled up [46]. We emphasize that *none* of these results (hardness in the absence of noise or easiness at fixed noise rate) is conclusive regarding how the difficulty of RCS grows over a particular range of system sizes given a particular error rate. Easiness results suggest that at sufficiently large noise rates, RCS may be classically feasible at all system sizes. But it is natural to expect that as error rates are reduced, the system sizes over which the asymptotic difficulty of noiseless RCS controls the empirical hardness will grow [47].

Ultimately, which set of results control the behavior

of classical RCS in the range of system sizes and error rates accessible to experiments is unclear, but one thing is clear: The larger one can make a quantum computer while continuing to push down error rates (for example, in a manner that maintains overall circuit fidelities while increasing N), the more likely it is that we will find tasks at which non-error-corrected quantum computers dramatically outperform the best classical algorithms. The high gate fidelities and arbitrary connectivity afforded by the trapped-ion QCCD architecture have enabled RCS to be carried out in a computationally challenging regime and at completely unprecedented fidelities, leaving open considerable room to scale such demonstrations up evenwithout further progress in reducing gate error rates. We are confident that H2 is by no means near the boundary of how far such demonstrations can be pushed using the QCCD architecture. For example, increasing system sizes while also reducing memory errors, circuit times, and 2Q error rates all appear achievable with current technologies by moving towards natively 2D trapping architectures [36, 37], and switching to qubit ions (such as $^{137}Ba^+$) that afford better SPAM fidelities than $^{171}Yb^+$ [48] and admit visible wavelength laser-based 2Q gates with more favorable error budgets. Given that RG circuits require such low depths to become hard to simulate (and a fixed fraction of qubits contribute to the worstcase hardness of simulation even as N is scaled up at constant depth), near-term scaling progress in the QCCD architecture should enable the faithful execution of quantum circuits whose simulation lies well beyond the reach of any conceivable classical calculation.

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DATA AVAILABILITY

All data presented, along with OpenQASM descriptions of the circuits from which the data was measured, are available at [29].

APPENDICES

A1. PRIMITIVE OPERATION BENCHMARKS AT N = 56

A. State-preparation and measurement (SPAM) experiment

State-preparation and measurement (SPAM) errors are measured with two experiments preparing all eight gatezone qubits in the $|0\rangle$ (and $|1\rangle$) state and measuring how often the incorrect '1' (and '0') outputs are returned. The associated probabilities (the ratio between observed wrong outcomes and the number of trials) are denoted p(1|0) and p(0|1), respectively. Due to the nature of the photon counting measurement [49] there is an imbalance between probabilities $p(1|0) = 3.8(7) \times 10^{-4}$ and p(0|1) = $26(2) \times 10^{-4}$. The average [p(1|0) + p(0|1)]/2 is reported in Tab. I as the SPAM error $p_{\text{SPAM}} = 1.47(9) \times 10^{-3}$. Uncertainty is calculated from the standard binomial confidence interval.

B. 1Q randomized benchmarking (1Q RB)

1Q randomized benchmarking (1Q RB) was performed on the eight gate-zone qubits with standard Clifford randomization [50]. We used sequence lengths [2, 512, 2048] each with 4 randomizations and 100 shots per randomization as shown in Fig. A1. The RB decay rate λ_{1Q} is estimated by fitting the survival probability from each sequence length p(m) with the first-order RB decay equation $p(m) = A\lambda_{1Q}^m + 1/2$ [50], where the asymptote is fixed to 1/2 by randomizing the final output state [51]. The average 1Q gate infidelity is calculated by combining the results over all eight gate-zone qubits and converting the RB decay rate to an average infidelity per 1Q Clifford to give $\epsilon_{1Q} = (1 - \lambda_{1Q})/2 = 2.9(4) \times 10^{-5}$. Uncertainty is calculated from a semi-parametric bootstrap resampling and shown with a one-sigma standard deviation [52, 53].

C. 2Q randomized benchmarking (2Q RB)

2Q randomized benchmarking (2Q RB) was performed on the eight gate-zone qubits with standard Clifford randomization [50]. We used sequence lengths [2, 32, 128] each with 4 randomizations and 100 shots per randomization. 2Q RB was repeated seven total times interspersed over the entire data collection and the results were combined and analyzed together as shown in Fig. A2. The RB decay rate λ_{2Q} is estimated by fitting the survival probability from each sequence length p(m) with the firstorder RB decay equation $p(m) = A\lambda_{2Q}^m + 1/4$ [50], where the asymptote is fixed to 1/4 by randomizing the final



FIG. A1. 1Q RB decay curve for all four gate zones (labeled DG01-DG04 in the legend) each with two qubits (dashed lines, the two qubits labeled as "left" and "right") and combined estimate averaged over all eight gate-zone qubits (solid line).

output state [51]. The average 2Q gate infidelity was estimated by combining all four pairs of gate-zone qubit's 2Q RB data and scaling the average 2Q Clifford infidelity by the average number of $U_{ZZ}(\pi/2)$ gates per 2Q Clifford (1.5) to give $\epsilon_{2Q} = 3(1 - \lambda_{2Q}^{2/3})/4 = 1.57(5) \times 10^{-3}$. Uncertainty is calculated from a semi-parametric bootstrap resampling and shown with a one-sigma standard deviation [52, 53].



FIG. A2. 2Q RB decay curve for all four gate zones (labeled DG01-DG04 in the legend, dashed lines) and combined estimate averaged over all four gate zones (solid line).



FIG. A3. (a) Transport 1Q RB data and decay curves for each qubit number N at which the fidelity is estimated in the main text. (b) Transport 1Q RB data and decay curve for the N = 40 verification data set collected subsequent to the rest of the data. (c) Memory error per qubit per layer extracted from the decay curves in (a), along with the logistic function model described in the text.

D. Transport one-qubit randomized benchmarking (Transport 1Q RB)

Transport 1Q randomized benchmarking (transport 1Q RB) was performed on up to all 56 qubits with random 1Q unitaries selected from SU(2). In transport 1Q RB, rounds of Haar-random 1Q random unitaries are interleaved with random transport operations. The random transport operations are selected to mimic the circuits used in the main text and are implemented with a dummy 2Q gate that forces the ion transport and cooling but does not apply the lasers that generate the 2Q gate. We used sequence lengths [4, 16, 32, 48, 64, 96] each with 10 randomizations and 10 shots per randomization, at each $N \in [16, 24, 32, 40, 48, 56]$. The data for each qubit was accumulated and analyzed as a 1Q RB experiment (as detailed above) performed in parallel across all Nqubits, as displayed in Fig. A3a, allowing us to extract an error per qubit that accounts for memory errors accrued during the random transport as well as errors from the 1Q gates. A second transport 1Q RB experiment was also executed at N = 40 (see Fig. A3b), interleaved with the verification set of N = 40 RCS circuits whose results are displayed in Fig. 9c, since these circuits were executed subsequent to the rest. In Tab. A1 we report the resulting estimate of memory error per qubit per layer extracted from each experiment. Uncertainty is calculated from a non-parametric bootstrap resampling with 1000 resamples and is shown with a one-sigma standard deviation.

In order to produce estimates of the fidelity from gate counting of circuits at intermediate qubit numbers in Fig. 9b, we require a model for the memory error at all possible qubit numbers. As the qubit number is increased towards the maximum of 56 supported by the device, the time required for a full round of transport operations increases and eventually plateaus (since there are always

Number of qubits	$\epsilon_{\rm mem}~(\times 10^{-4})$	$\varepsilon(N)~(\times 10^{-3})$
N = 16	1.5(4)	2.4(2)
N = 24	2.5(4)	2.8(2)
N = 32	4.2(4)	3.1(2)
N = 40	4.1(5)	3.2(2)
N = 40 (verification set)	4.6(5)	3.4(1)
N = 48	4.1(4)	3.2(1)
N = 56	4.0(4)	3.2(1)

TABLE A1. Memory error per qubit per layer extracted from a separate transport 1Q RB experiment at each fixed qubit number N, and the resulting effective process infidelity per 2Q gate $\varepsilon(N)$.

56 qubits in the trap, once a sufficient fraction of the qubits are involved in a given program there is no longer a substantial increase in transport time with further increase in qubit number; see Fig. A4). We emphasize that the time reported for sorting at N = 32 is larger than that reported in Ref. [6] for N = 32, because the time required for N = 32 now includes transport operations on all 56 qubits (24 of which are loaded in the trap but not involved in the circuit). As an empirical model for the resulting memory error as a function of N (interpolating between zero error as $N \to 0$ and a maximum level of error as $N \to 56$) we employ a logistic (sigmoid) function L of the form

$$L(N) = \frac{A}{1 + e^{-k(N - N_0)}},$$
 (A1)

representing interpolation between extreme values of 0 and A, centered at N_0 , with slope governed by k. A nonlinear least-squares fit of L(N) to the measured memory error as a function of N yields the fit parameters $A = 4.1(2) \times 10^{-4}$, $N_0 = 20(2)$, k = 0.18(5), and is depicted in Fig. A3c. Propagating these fit values and



FIG. A4. Average time per shot on the H2 quantum computer for each type of circuit at d = 12 as a function of number of qubits, N. Since there is no transport 1Q RB data at sequence length 12, we take the transport 1Q RB data from sequence length 16 and rescale times linearly to length 12 (see Fig. A5 for evidence that the time per layer of transport 1Q RB sequences scales nearly perfectly linearly with depth).

their uncertainties allows estimates of the memory error per qubit per layer at all N, continuously interpolating between N = 16 and N = 56. In combination with the other component benchmarks reported in Tab. I, the gate-counting model in Eq. (11) then supplies the estimates of the fidelity as a function of N reported as $F_{\rm GC}$ in Fig. 9b.

It is interesting to examine to what extent shot time on the H2 quantum computer depends on circuit structure. In Fig. A5 we provide evidence that for RCS and transport 1Q RB circuits, which have identical gate topologies but different gate angles, the average time per shot at N = 56 is essentially identical and nearly perfectly linear with circuit depth. Mirror benchmarking circuits. on the other hand, are expected to have one fewer layers of transport compared to RCS and transport 1Q RB circuits, since there should be no transport required to execute the first layer in the backwards half of the circuit. In Fig. A6 we investigate the extent to which this is true by comparing the shot times of RCS and MB circuits to the times of the corresponding transport 1Q RB circuits at the same depth, computed by interpolating the linear model in Fig. A5. RCS circuits demonstrate essentially identical timings to the corresponding transport 1Q RB circuits. While MB circuits roughly demonstrate the expected (d-2)/(d-1) scaling, they also have a constant multiplicative overhead of approximately 2.2% compared to transport 1Q RB that may be due to differences in the required transport to execute the mirror circuit.



FIG. A5. Average time per shot on the H2 quantum computer for each type of circuit at N = 56 as a function of depth. For the transport 1Q RB (and RCS) data, the execution time is essentially exactly linear: fitting all depths out to 96 of the transport 1Q RB data yields the model: time = (0.080d +0.019) s., as depicted. Note that the range of the x axis is restricted to 32 in the plot to make it easier to visualize the MB and RCS data. Uncertainties are smaller than point size.



FIG. A6. The ratios of average shot time at each depth for N = 56 MB and RCS circuits to the expected time of transport 1Q RB circuits by interpolating the linear model in Fig. A5.

A2. COMPARISON OF VARIOUS FIDELITY ESTIMATORS

It is generally expected that the fidelity of a sufficiently deep random circuit will be roughly equal to the probability that no constituent operation has failed; we refer



FIG. A7. (a) Deviations of F_{XEB} from unity in the absence of noise as a function of qubit number N for RG circuits of various depths. Each curve shows the median over 100 circuits, and shaded regions represent one standard error. (b-d) Distributions of $|F_{\text{XEB}} - 1|$ over circuits for various N at (b) d = 8, (c) d = 10, and (d) d = 12. The histograms are smoothed probability densities of log $|F_{\text{XEB}} - 1|$ over 100 random circuits at the stated value of N (different N offset vertically, labeled on the left of each plot) and d. Small values indicate that the distribution of probabilities at the output of a given circuit is well converged (in its second moment) to the Porter-Thomas distribution. Over the limited range of N studied, it is clear that the vast majority of the distribution lies at values well below 1% for $d \ge 10$ and $N \ge 16$.

to this fidelity estimation strategy as gate counting, and label the fidelity estimated in this manner F_{GC} . To estimate the actual fidelity of a circuit experimentally (in the regime where it is not computable even assuming an accurate noise model is known), we use the mirror benchmarking technique outlined in Ref. [38] adapted to the random circuits run here. In particular, to assess the fidelity of a depth-d random graph (RG) circuit we take a depth-d/2 RG circuit (assuming d is even) and then append to it the same circuit with all gates inverted and run in the reverse order, such that the overall circuit (ideally) implements the identity map. Randomized compiling [40] is applied to the reverse circuits to prevent the possible cancellation of coherent errors. We choose the initial state to be a random computational basis state to remove any potential SPAM bias, measure the fraction of shots that return the (randomized) initial bit string, and denote this fraction $F_{\rm MB}$. Strictly speaking, the decay of $F_{\rm MB}$ with depth provides an estimate of the variance of the Pauli fidelities of the per-layer error channel of the circuit. From this estimate, the per-layer fidelity can be bounded. However, as the numerics below confirm, $F_{\rm MB}$ provides an excellent estimate of the overall circuit fidelity even under a highly realistic local noise model.

For circuits deep enough that the output distribution of the ideal circuit is well-approximated by the Porter-Thomas distribution, we also expect the linear crossentropy fidelity F_{XEB} to agree with both of the above estimates. In this section, we analyze to what extent

$$F \approx F_{\rm MB} \approx F_{\rm XEB}$$
 (A2)

is valid for the circuits in the manuscript. First, we assess the convergence to Porter-Thomas of the output distribution of ideal circuits as a function of depth and system size. At the depths where such convergence is adequate, we then run numerical simulations with a detailed noise model of our machine at a variety of moderate system sizes, checking that all three quantities agree in a manner that is very nearly system-size independent when the noise is scaled in such a manner that the probability of a gate failure per layer of 2Q gates is held fixed.

A. Convergence of RG circuits to Porter-Thomas without noise

For insufficient depths, the probabilities of bitstrings at the output of RG circuits will not be distributed according to the Porter-Thomas distribution even in the absence of circuit noise, and linear XEB fails to be a good fidelity estimator. However, Fig. A7 shows that the convergence to Porter-Thomas in the second moment (equivalent to $|F_{\text{XEB}} - 1| \rightarrow 0$ in the absence of noise) happens very quickly as the depth is increased, with the bulk of the distribution over 100 random circuits showing fluctuations well below the 1% level for $d \ge 10$. In Fig. A8 we show the full distribution of binned output probabilities at depths $d \in \{4, 6, 8, 10\}$. Even for N = 16 (the smallest number of qubits for which data is presented in the paper), upon averaging the distribution over 100 circuits we find that the convergence to Porter-Thomas is excellent over the entire distribution by depth 10 (Fig. A8(a)). By N = 28 we find good convergence at depth 10 even for a single random circuit (Fig. A8(b)).

B. Numerical studies with a detailed noise model

The simulations reported in this section utilize a noise model consisting of 2Q stochastic Pauli channels attached to each $U_{ZZ}(\pi/2)$ gate and a memory error attached to each qubit during the idling time between sequential 2Q



FIG. A8. Histograms of output probabilities for circuits on (a) N = 16 qubits and (b) N = 24 qubits, both at various depths. All probabilities (horizontal axis) are rescaled by 2^N , and the vertical axis is the normalized probability density function (PDF) over rescaled probabilities. By depth 10, the distribution is well-converged to Porter-Thomas upon averaging over a 100 circuits for N = 16, and self-averages to Porter-Thomas for a single circuit by N = 28.

gates that are applied to it. The stochastic Pauli channel is inferred from cycle benchmarking data [54], taken on H1-1 and rescaled according to the measured 2Q RB fidelity on H2 such that its average infidelity is the measured $\epsilon_{2Q} = 1.57 \times 10^{-3}$. The memory error per qubit per layer is inferred from transport 1Q RB data measured at N = 56 (see Appendix A1), and the associated average infidelity is $\epsilon_{\text{mem}}(56) = 4.0 \times 10^{-4}$. While the transport 1Q RB data does not distinguish between different types of memory errors, we assume the per-qubit-perlayer memory error is entirely attributable to coherent dephasing; while we expect memory errors to be only partially coherent, we make this assumption because it seems most likely to challenge the assumptions underlying the various fidelity estimates. Finally, we rescale all noise rates by a factor of 56/N for simulations performed on N qubits, such that the error rate per layer of 2Q gates is held fixed to the N = 56 value as we change N. The gate-counting estimate works by converting these error rates into process infidelities, and then multiplicatively composing the process fidelities of the circuit components as

$$F_{\rm GC} = \left(1 - \varepsilon(N)\right)^{Nd/2},\tag{A3}$$

where here

$$\varepsilon(N) = \frac{56}{N} \left(\frac{5}{4} \epsilon_{2Q} + 2 \times \frac{3}{2} \epsilon_{\text{mem}}(56) \right)$$
(A4)

is the rescaled effective process infidelity per 2Q gate. Figure A9(a) shows calculations of the actual circuit fidelity compared to this gate-counting estimate for various system sizes and over a range of circuit depths. The fidelities are obtained by quantum trajectories simulations, and we average over 100 random circuits taking 1024 trajectories for each. Error bars represent 1σ confidence intervals obtained by bootstrap resampling of the numerical data (1000 resamples). Figure A9(b,c) show simulations of $F_{\rm MB}$ and $F_{\rm XEB}$ under the same conditions (quantum trajectories simulations averaging over 100 circuits with 1024 shots per circuit, error bars from bootstrap resampling). An important conclusion of the numerical data in Fig. A9 is that the data collapses well for all N simulated, strongly suggesting that the observed similarity between the various fidelity estimates should hold at N = 56.

Figure A10 shows comparisons of F, F_{GC} , F_{MB} , and F_{XEB} at the largest simulated system size, N = 24. All three fidelity estimates agree reasonably well with the computed F, though there are small systematic differences between the various estimates that have a known physical origin [13]. The gate-counting argument assumes that if there are one or more errors in the circuit, the output state will be orthogonal to the ideal one. While this assumption is approximately true for very deep circuits, errors near the beginning of the circuit (when the state is only weakly entangled) do not effectively orthogonalize the state, and therefore gate counting underestimates the true fidelity. Both $F_{\rm MB}$ and $F_{\rm XEB}$ also reflect this imperfect state orthogonalization, but now due to errors at either the beginning or end of the circuit, causing these estimators to agree well with each other but to *overestimate* the true fidelity by the same amount that gate counting underestimates it. Note that the small discrepancies between these various fidelity estimates and the true fidelity are generally comparable to or smaller than the error bars reported in the manuscript, and we interpret the numerical data in Figs. (A9, A10) as confirmation that all three fidelity estimates — $F_{\rm GC}$, $F_{\rm MB}$, and $F_{\rm XEB}$ — are suitably accurate for our purposes. In particular, this data supports our expectation that F_{XEB} of the data taken from 56-qubit circuits (and available at [29]) should agree well with the mirror benchmarking return probabilities for those circuits, despite



FIG. A9. Fidelity collapse when scanning N. The three fidelity estimators plotted are (a) True fidelity of the output state with respect to the ideal state; (b) Mirror benchmarking fidelity, with the fidelity at depth d inferred from the return probability of a mirrored depth-d/2 circuit; (c) F_{XEB} , the linear cross-entropy benchmarking fidelity. All simulations are randomized over 100 random circuits, and all error bars (generally too small to resolve) are 1σ confidence intervals from bootstrap resampling.



FIG. A10. Comparing various fidelities at N = 24, which was the largest system size we performed noisy simulations for. Error bars (for F and $F_{\rm MB}$) and the shaded region (for $F_{\rm XEB}$) are 1σ confidence intervals obtained by bootstrap resampling.

the fact that we have not computed the cross-entropy of that data ourselves (and we do not know how it could be computed except possibly at the lowest depths with significant effort). However, because $F_{\rm GC}$ underestimates the true fidelity while $F_{\rm MB/XEB}$ overestimates it, the cumulative affect is a resolvable (at the level of our error bars) discrepancy between $F_{\rm GC}$ and $F_{\rm MB/XEB}$. Since the discrepancy arises due to the inadequate discounting of errors near the early and late-time boundaries of the circuit by $F_{\rm GC}$, we fit the gate-counting fidelity at a shifted depth $d \rightarrow d - \delta$ to the $F_{\rm MB}$ numerics at N = 24 to obtain a depth shift of $\delta \approx 1.12$. We use this inferred depth shift to report the gate-counting fidelities in Fig. 9 of the manuscript.

A3. QUANTIFYING UNCERTAINTIES IN THE EXPERIMENTAL DATA

To compute the uncertainties associated to measurements of F_{XEB} and F_{MB} , we employ non-parametric bootstrapping [53]. An experimental data set is a collection of observed bitstrings $\{x_j\} = S$, and for all $F_{\text{XEB/MB}}$ data reported in Fig. 9, each data point corresponds to an experiment in which 50 random circuits are sampled 20 times each, for a total of 1000 samples per experiment. For a given outcome x_j , we let $f_j = 2^N P(x_j)$ (with $P(x_j)$ the probability of x_j for the ideal circuit) in the case of F_{XEB} , or $f_j \in \{0, 1\}$ with "1" or "0" indicating a "right" or "wrong" value in the case of $F_{\rm MB}$. We let f be the expectation value of f_j , and \hat{f} its estimate obtained by averaging f_j over the experimental outcomes: $\hat{f} = \frac{1}{N_s} \sum_j f_j$, where N_s is the total number of samples. In the non-parametric bootstrap procedure, one creates a large number r of synthetic data sets $\{S_1, S_2, \ldots, S_r\},\$ each one obtained by resampling the experimental data with replacement. The quantity of interest is then averaged over the data in each synthetic data set to produce a distribution of estimates $\{f_1, f_2, ..., f_r\}$. A 1 σ confidence interval $[f_{-1\sigma}, f_{+1\sigma}]$ is assigned to this distribution according to the appropriate 1σ quantiles, and a confidence interval for f is then constructed by reflecting the bootstrapped confidence interval about twice the empirically observed mean \hat{f} ,

$$CI = [2\hat{f} - f_{+1\sigma}, 2\hat{f} - f_{-1\sigma}].$$
 (A5)

This reflection is intended to remove bias in the construction of the bootstrap interval arising from the fact that



FIG. A11. Standard deviation of F_{XEB} computed over 100 random circuits, and plotted versus system size for various depths. For this calculation, F_{XEB} is computed for each circuit by full density matrix simulation using a depolarizing noise model for the 2Q gates (with depolarizing parameter at each N rescaled to have the same error-per-layer as the measured value for H2 at N = 56). The standard deviation falls below 0.01 as N is increased for all but the shallowest (d = 8) circuits, which saturate at a slightly higher value with increasing N.

the mean of the bootstrap distribution may not match the empirically observed mean.

We consider two methods for resampling from the observed data set. One possible method is to pool together all of the samples associated to a particular experiment and resample from this combined pool, which we call the aggregate resampling method. Another, which we call the double resampling method, is to first resample from the pool of circuits associated to a particular experiment, and then to further resample from the observed samples for each of the resampled circuits. In general, as we provide evidence for below, the double resampling method results in a more conservative (wider) confidence interval. To maintain consistency with previously reported methods for randomized benchmarking [6], we choose the double resampling method to quantify uncertainties of component benchmarks. However, which confidence interval is most appropriate depends on the extent to which the underlying distribution being sampled from for each circuit fluctuates from circuit to circuit. To understand which is more appropriate in the context of estimating $F_{\rm MB}$ and $F_{\rm XEB}$, we first assess to what extent these quantities vary from circuit-to-circuit given a fixed error model.

From numerics on small system sizes, we believe the fluctuations in both quantities from circuit to circuit are well below the 1% level for the circuits run in this paper $(d \ge 8 \text{ at } N = 56 \text{ and } d \ge 12 \text{ at all } N \ge 16)$. In the case of F_{XEB} , evidence for this statement is provided in Fig. A11. There, we perform density matrix simulations of noisy circuits at small systems sizes $(N \le 14)$, and ob-

serve that the standard deviation of F_{XEB} over circuits falls below 10^{-2} for all depths $d \ge 12$. A more relevant source of fluctuations from circuit to circuit comes from drift in machine performance. Considering that all circuits for all experiments are randomly interleaved in time, while all shots for a single circuit are taken in rapid succession, it is reasonable to model drifts in machine performance by assigning each circuit a random but fixed value of ε , drawn from a distribution around its experimentally measured average. For F_{XEB} , we model a single circuit as sampling from a model probability distribution that is a convex mixture of the ideal Porter-Thomas distribution (with probability $F(\varepsilon)$) and the uniform distribution (with probability $1 - F(\varepsilon)$). For $F_{\rm MB}$ we model each circuit as a Bernoulli trial (biased coin flip) with a probability $F(\varepsilon)$ of returning the correct bit string and probability $1 - F(\varepsilon)$ of a wrong bitstring. In both cases the circuit fidelity F depends on the per 2Q gate process infidelity ε , which we take to be a random variable that is Gaussian-distributed about its experimental mean value $\varepsilon_{\rm exp} \approx 3.2 \times 10^{-3}$ with standard deviation $\mu \times \varepsilon_{\rm exp}$. Diagnostic and calibration data from the time period during which the data reported in Sec. IV was taken suggests a conservative upper bound $\mu \lesssim 0.2$. The set of all probability distributions over the collection of outcomes obtainable in this way is referred to as the *experimental* model.

We use this experimental model to perform a coverage analysis by simulating $N_E = 4000$ experiments, each with 50 circuits and 20 shots per circuit. For each data set we perform both aggregate bootstrapping and double bootstrapping using r = 4000 resamples. We then compute bootstrapped confidence intervals for each of the N_E simulated experiments from the synthetic bootstrap data and the empirical mean from that experiment, and compute the fraction of experiments for which the true value (estimated by the mean across all experiments) is contained within that confidence interval, referring to that fraction as the *coverage*. A proper 1σ confidence interval must provide coverage $\geq 68.27\%$ for all distributions in the experimental model, and this level is denoted by the black dashed line in Fig. A12. In general, for the expected $\lesssim 20\%$ fluctuations in $\varepsilon \ (\mu \lesssim 0.2)$ we see that aggregate resampling provides a confidence interval for $F_{\rm XEB}$ with the required coverage, while double resampling provides excessive coverage (resulting in an overly conservative confidence interval). For $F_{\rm MB}$ the coverage of aggregate resampling falls off faster, requiring $\mu \lesssim 0.1$ to be adequate. In either case, for extremely large fluctuations in ε ($\mu = 1$) we see that aggregate resampling fails to provide adequate coverage (and thus underestimates the size of the correct 1σ confidence interval), while the coverage of double resampling remains adequate. Since we expect the actual circuit fluctuations in ε to be $\lesssim 20\%$, we believe that aggregate resampling is likely more appropriate for assigning confidence intervals to our $F_{\rm XEB}$ data, though it may slightly underestimate the appropriate confidence intervals for $F_{\rm MB}$. Given that the confi-



FIG. A12. Coverage analysis for aggregate bootstrapping and double-bootstrapping applied to simulated experiments for both $F_{\rm xEB}$ (upper) and $F_{\rm MB}$ (lower). Double bootstrapping generally over-covers the data, most severely in the small μ limit where circuit-to-circuit fluctuations in the underlying distribution are small. Aggregate resampling generally provides an appropriate confidence interval for $\mu < 0.2$ for $F_{\rm XEB}$ (and $\mu < 0.1$ for $F_{\rm MB}$), but can under-cover the data in either case at large μ (especially for small values of the circuit fidelity F.)

dence intervals are larger for $F_{\rm XEB}$, and in the interest of consistency, we opted to use the aggregate resampling method to report *all* 1 σ error bars on both $F_{\rm MB}$ and $F_{\rm XEB}$ in the manuscript.

The larger variance estimate provided by the double resampling method can be explained analytically as follows. Consider the probability of any particular individual shot appearing k times when N_s shots are resampled. In the aggregate resampling method, this probability is binomially distributed:

$$\mathbb{P}_{\text{agg}}(k) = \left(\frac{1}{N_s}\right)^k \left(1 - \frac{1}{N_s}\right)^{N_s - k} \binom{N_s}{k}.$$
 (A6)

In the double resampling method, the probability that a particular labeled shot appears k times depends on how many times its corresponding job is resampled. If there



FIG. A13. Probability distributions $\mathbb{P}(k)$ of resampling a single labeled shot k times, depending on the aggregate or double resampling methods with 1000 shots binned into a variable number N_j of jobs and $1000/N_j$ shots per each job. In all cases except the $N_j = 1$ and $N_j = 1000$ limits where the aggregate and double resampling methods are equivalent, the double resampling distributions contain significantly higher weight at k = 0 and $k \geq 3$. Numerically modeled points with error bars are overlaid on the solid line representing the analytic expressions in Eqs. (A6), (A7).

are N_j total jobs, with $N_{\rm per}$ shots per job and $N_s = N_j N_{\rm per}$,

$$\mathbb{P}_{\text{doub}}(k) = \sum_{j=0}^{N_j} \left(\frac{1}{N_j}\right)^j \left(1 - \frac{1}{N_j}\right)^{N_j - j} \binom{N_j}{j} \mathbb{P}(k \mid j),$$
(A7)

where $\mathbb{P}(k \mid j)$ is the probability that a given labeled shot appears k times given that its corresponding job is resampled j times. To compute $\mathbb{P}(k \mid j)$, one must consider all of the ways that the k appearances can be spread over the j job resamples. Note that the k appearances may be restricted to only a subset of the j resamples of size n_b "bins", as long as $k \leq n_b N_{per}$. Therefore, we compute $\mathbb{P}(k \mid j)$ by summing over the set of partitions of k of fixed size n_b , $P_{k,n_b} = \{(p_1, \ldots, p_{n_b}) \in (\mathbb{Z}^+)^{n_b} \mid \sum_i p_i = k\}$ as follows

$$\mathbb{P}(k \mid j) = \sum_{n_b=0}^{j} \left[\binom{j}{n_b} \left(1 - \frac{1}{N_{\text{per}}} \right)^{(j-n_b)N_{\text{per}}} \times \sum_{P_{k,n_b}} \mathbb{P}(k \mid P_{k,n_b}) \right].$$
(A8)

The first term in the exterior sum counts the number of ways of choosing the n_b bins from the j job resamples. The second term is the standard binomial term accounting for the remaining $j - n_b$ jobs, each with $N_{\rm per}$ shots, where the labeled shot does not appear. The interior sum is over $\mathbb{P}(k | P_{k,n_b})$, the probability of the k appearances being distributed amongst bins according to each possible partition P_{k,n_b} . Note that the set of all such partitions includes "equivalent" partitions where the same set of p_i are permuted over the different bins n_b , which are counted separately in the sum. This final conditional probability is simply the product of binomial distributions over the n_b bins:

$$\mathbb{P}(k \mid P_{k,n_b}) = \prod_{i=1}^{n_b} \left(\frac{1}{N_{\text{per}}}\right)^{p_i} \left(1 - \frac{1}{N_{\text{per}}}\right)^{N_{\text{per}} - p_i} \binom{N_{\text{per}}}{p_i}.$$
(A9)

The distributions $\mathbb{P}_{agg}(k)$ and $\mathbb{P}_{doub}(k)$ are depicted in Fig. A13 along with data averaged across 100 instances of numerical resampling experiments in which 1000 resamples were drawn from 1000 shots by either method and different job sizes. For all job sizes except $N_j = 1$ and $N_i = 1000$ where the double resampling method reduces to aggregate resampling, $\mathbb{P}_{\text{doub}}(k)$ contains significantly higher weight at k = 0 and $k \ge 3$. One interpretation of this result is that in a given resampling experiment using the double resampling method, the data tend to "clump", favoring multiple samples of the same shots and excluding other shots entirely, owing to the fact that each resampling experiment has a chance to exclude some jobs entirely. The higher variance estimate provided by the double resampling method can consequently can be viewed as an instance of Sheppard's correction [55] in which binned data tend to exhibit slightly higher variance estimates; a tendency to replace individual shots by multiple occurrences of the same shot is similar to replacing all data in a bin with the midpoint of the bin.

A4. CONSTRUCTION OF CIRCUITS WITH RANDOM GEOMETRIES

Considering each qubit as a node in a graph, a set of edges \mathcal{E} connecting those nodes is said to be mutually disjoint if no two edges in \mathcal{E} contain the same node. If we associate a 2Q gate to each edge in \mathcal{E} , those gates have mutually non-overlapping support and can all be executed (in principle) in parallel. In a slight abuse of notation we use \mathcal{E} to also denote the set of 2Q gates associated to the edges in \mathcal{E} , and we refer to \mathcal{E} as a single 2Q-layer of a circuit. Each gate in \mathcal{E} will be the H2 quantum computer's native perfect entangler $U_{ZZ}(\pi/2) = e^{-i(\pi/4)Z\otimes Z}$ (see Appendix A7 for further discussion regarding this gate choice). Similarly, let \mathcal{S} denote a set of 1Q gates assigned to each qubit; we refer to S as a single 1Qlayer of a circuit. Each 1Q gate $S \in S$ is chosen to be a Haar-random SU(2) gate, which can be decomposed as $S = R_z(\psi) U1q(\theta, \phi)$. Here

$$U1q(\theta,\phi) = e^{-i(\theta/2)(\hat{X}\cos\phi + \hat{Y}\sin\phi)}$$
(A10)

is our native 1Q gate, and $R_z(\psi)$ is a z-rotation that is performed in software (i.e. by pushing the z-rotation through future 1Q gates and modifying their phases accordingly). A random depth-d circuit is then defined by interleaving such layers as

$$C = \mathcal{S}_d \mathcal{E}_d \mathcal{S}_{d-1} \mathcal{E}_{d-1} \dots \mathcal{S}_1 \mathcal{E}_1 \mathcal{S}_0.$$
 (A11)

A powerful feature of QCCD architecture is the flexibility to choose which pairs of qubits are gated in a given 2Q layer: Regardless of the physical locations of the qubits after the previous layer, any set \mathcal{E} can contain arbitrary pairs and the associated gates will be executed directly (e.g. without logical SWAP gates) by physically rearranging the ions such that the qubits associated to each 2Q gate in \mathcal{E} are located next to each other. In this work we consider the ensemble of random circuits in which the sets $\mathcal{E}_1, \ldots, \mathcal{E}_d$ are obtained via the following procedure:

- 1. Select a random d-regular graph \mathcal{G} on N vertices.
- 2. Find a proper edge coloring of \mathcal{G} with d colors.
- 3. Assign a unique index $j = 1, \ldots, d$ to each color in the edge coloring, and put each edge with color j into the set \mathcal{E}_j .

A proper edge coloring is defined as an assignment of a color to each edge in a graph such that no two edges of the same color impinge on the same node, and hence each \mathcal{E}_i is a proper (mutually disjoint) layer of 2Q gates (see Fig. A14(a) for an example of a proper edge coloring of a 3-regular graph on 6 nodes using 3 colors). By Vizing's theorem, \mathcal{G} is guaranteed to have a proper edge coloring using a minimum number of colors equal to either d (in which case \mathcal{G} is referred to as class I) or d+1 (in which case \mathcal{G} is referred to as class II). Note that in step 2 of the above procedure we implicitly assume that the sampled graph is class I. While this assumption is not guaranteed to be true, it is known that random regular graphs of degree $d \geq 3$ are asymptotically almost always (i.e. with probability approaching 1 for $N \to \infty$) class I [56, 57], and all d-regular graphs with even N and $d \geq 2\lceil N/4 \rceil - 1$ are provably class I [58]. Empirically, we are able to find proper *d*-colorings of all but a very small subset of randomly sampled graphs in the ranges of (N, d) that we have considered. In the rare event that no proper dcoloring is found in step 2, we reject the graph and return to step 1.

A5. BOUNDS ON CONTRACTION DIFFICULTY OF RANDOM-GEOMETRY CIRCUITS

To any unitary quantum circuit C one can associate a tensor network \mathscr{T}_C in which gates are complex-valued tensors and wires (qubits) are the indices/legs of those



FIG. A14. (a) To construct a depth-3 circuit on 6 qubits, we first select a random 3-regular graph on n vertices, denoted \mathcal{G} , and assign to it a proper edge coloring using 3 colors. (b) \mathcal{G} induces the circuit C shown by associating each vertex (edge) in \mathcal{G} to a qubit (2Q gate) in C; each 2Q-gate layer of C is in correspondence with a given color in the coloring of \mathcal{G} . Qubits are assumed (without loss of generality since random 1Q gates are applied immediately after initialization) to be initialized in the $|0\rangle$ state, and layers of 1Q gates in C have been absorbed into the 2Q gates for clarity. The probability that the circuit outputs a given product state (here the state $|011010\rangle$) can be represented as a tensor network as shown in (c) by associating each 2Q gate to a rank-4 tensor. (d) Upon Schmidt-decomposing those gates and absorbing the rank-1 tensors corresponding to input and output states into adjacent 2Q gate tensors, we obtain the tensor network \mathscr{T}_C . (e) An equivalent redrawing of \mathscr{T}_C reveals its similarity to the underlying graph \mathcal{G} from which the circuit was generated.

tensors. In this representation, 1Q gates become rank-2 tensors (one incoming and one outgoing qubit wire) and 2Q gates become rank-4 tensors (two incoming and two outgoing qubit wires). The initial state $|\psi_j\rangle$ of each input qubit j is a rank-1 tensor, and the output of the tensor network (uncontracted legs) represents the quantum state at the output of the circuit, $|\Psi\rangle = C \bigotimes_{i} |\psi_{i}\rangle$. The overlap between $|\Psi\rangle$ and a particular tensor-product of single qubit states $\bigotimes |\varphi_i\rangle$ is then obtained by contracting each output leg of the tensor network with a rank-1 tensor corresponding to the 1Q state $|\varphi_i\rangle$ associated to that qubit. As an example, in Fig. A14(b) we show the depth d = 3 quantum circuit C induced by the 3-regular graph \mathcal{G} shown in Fig. A14(a), as described in Appendix A4. The tensor network associated to this circuit, denoted \mathscr{T}_C , is shown in Fig. A14(d). Note that we have decomposed each rank-4 gate tensor into a tensor product of two rank-3 tensors as shown in Fig. A14(c). For the $U_{ZZ}(\pi/2)$ gates used here, this decomposition has Schmidt-rank two. Therefore, both the colored lines (originating from gates) and the black lines (originating from qubit wires) have dimension 2, and we need not distinguish between them when determining the time or memory cost of tensor contraction. We have also absorbed the rank-1 input and output tensors into the nearest gate tensor. Figure A14(e) shows how the tensor network \mathscr{T}_C is structurally similar to the graph \mathcal{G} from which the circuit C was generated.

A. Lower bound

To arrive at the TN \mathscr{T}_C in the form shown in Fig. A14(e) we have already decomposed each rank-4 2Q gate tensor into two rank-3 tensors. However, we could also consider the contraction cost of the original circuit TN (\mathscr{T}_C^0 , not shown in Fig. A14). The TN \mathscr{T}_C cannot be harder to contract than \mathscr{T}_C^0 , because one viable

contraction path for \mathscr{T}_C consists of first grouping each gate back to a single rank-4 tensor, thereby achieving \mathscr{T}_C^0 as an intermediate tensor (and this process occurs at much lower cost than future operations in contracting \mathscr{T}_C^0). Therefore, the contraction cost of \mathscr{T}_C lower bounds the contraction cost of the original circuit TN \mathscr{T}_C^0 , and we only need to lower bound the cost of contracting \mathscr{T}_C in the form shown in Fig. A14(e).

Below we will prove that for $d \geq 3$ and with probability (over the distribution of circuits considered) approaching 1 as $N \to \infty$, the contraction cost for our circuits obeys

$$\mathscr{C}_d = \lim_{N \to \infty} \frac{\log_2(\text{cost})}{N} \ge c \tag{A12}$$

for some constant 0 < c < 1. This result should be compared to the observation that $\mathscr{C}_d = 0$ in any local and finite-dimensional geometry. The underlying methodology is related to the work of Markov and Shi (see Theorem 1.7 in Ref. [19]), however the proof is more direct and requires very little graph-theoretic machinery; ultimately, it is based on the recognition that for circuits with gates drawn from graphs with good expansion properties, TN contraction requires forming intermediate tensors that either cut an extensive number of qubit wires, gates, or both.

 \mathscr{T}_C is composed of Nd original tensors, and its contraction into a scalar (a single rank-0 tensor whose value is the amplitude $\langle \Phi | C | \Psi \rangle$ for a particular output state $| \Phi \rangle$) proceeds as a sequence of individual contractions that can be represented as a rooted binary tree (see Fig. A15 for an example), with the original tensors as leaves and the final scalar as the root. Each vertex in the tree corresponds to a merged tensor during the contraction process, and its children (the two tensors merged to make it) are connected to it by edges. Each vertex can be labeled by its descendants, e.g. which of the leaves (original tensors) have been absorbed into the associated tensor, and those leaves are shown explicitly inside the vertices in Fig. A15. The tensor obtained by the j^{th} contraction is denoted \mathscr{T}_j , and we define its size $|\mathscr{T}_j|$ as its number of descendants (i.e. the number of original tensors that merged to form it). We refer to the number of legs of the tensor \mathscr{T}_j as its rank r_j . Because all edges of \mathscr{T}_C have dimension 2 (due to our gates being rank-2 entanglers), the contraction cost (measured in FLOPs) associated to a particular contraction tree is lower-bounded as

$$\cot \ge \max_{i} 2^{r_j}.$$
 (A13)

The cost of contracting \mathscr{T}_{C} is obtained by minimizing the contraction cost over all possible contraction trees. Note that there must be a smallest value of j such that $|\mathscr{T}_i| \geq Nd/3$ (i.e., as one proceeds with the contraction, there must be a first time when two merged tensors result in a final tensor of size at least Nd/3), and we call this intermediate tensor \mathscr{T}_{\min} . Since every other tensor has (by assumption) size less than Nd/3 when the j^{th} contraction happens, we also know that $|\mathscr{T}_{\min}| \leq 2Nd/3$. Our goal here is to ensure that both the set of original tensors contained in \mathscr{T}_{\min} and the set of all other tensors are *both* extensive, which will ultimately be used to ensure that an associated subset of the vertices of \mathcal{G} has a large edge boundary (which requires that the subset and its complement are both large). We could have used any number of tensors $k \times Nd$ with 0 < k < 1/2 (rather than our choice k = 1/3) when defining $\mathscr{T}_{\min}(1/2)$ is problematic since then \mathscr{T}_{\min} could contain almost every original tensor).

For simplicity of illustration let's assume that $|\mathscr{T}_{\min}| =$ (Nd/2), i.e. \mathscr{T}_{\min} is composed of exactly half of the primitive tensors. Figure A16 shows an example of \mathscr{T}_C for a 10-qubit depth-3 circuit in which we have labeled the Nd/2 original tensors forming \mathscr{T}_{\min} as filled circles (•), and all of the original tensors not merged into \mathscr{T}_{\min} as open circles (\circ). To each qubit in the circuit we can associate a *bag* of tensors belonging to the gates that act on that qubit; in the depth-3 example of Fig. A16 each bag (grey disk) contains exactly 3 tensors. The set of all bags can be decomposed as $\mathcal{C} \cup \mathcal{U} \cup \mathcal{P}$, such that \mathcal{C} contains the bags for which all constituent tensors have been contracted into $\mathscr{T}_{\min}, \mathcal{U}$ contains the bags for which none of the constituent tensors have been contracted into \mathscr{T}_{\min} , and \mathcal{P} contains the bags for which some but not all constituent tensors have been contracted into \mathscr{T}_{\min} .

It is helpful to consider the strategy of statevector simulation, in which all gates of a given color are absorbed sequentially, causing all bags to be in \mathcal{P} . More generally, each bag of type \mathcal{P} is associated with at least one qubitwire protruding from the intermediate tensor \mathscr{T}_{\min} , and choosing the set \mathcal{P} to be large corresponds to a predominantly space-like slicing of the network (e.g. created by slicing in a way that divides tensors at later times from those at earlier times), suffering a cost that is exponential in the number of qubits. A productive contraction strategy for sufficiently shallow spatially local lattices is to avoid bags of type \mathcal{P} entirely, corresponding to making time-like cuts through the tensor network such that only



FIG. A15. Representation of the contraction of a tensor network \mathscr{T} into a scalar as a rooted binary tree flowing from bottom (leaves) to top (root) (here we assume that \mathscr{T} has no open legs so that it can be contracted to a scalar, as in the case of a TN representing the probability amplitude of a given state at the output of a quantum circuit). Here \mathscr{T} is chosen to have 6 tensors, which are represented by the leaves of the tree (each is given a unique color), while every other vertex represents a merged tensor formed by contracting any legs shared by its two children. The root represents the final (scalar) value of the contraction.

gate wires protrude from \mathscr{T}_{\min} . Judiciously choosing the set \mathcal{C} (to have a small edge boundary) can greatly reduce the contraction cost relative to the statevector strategy. The fundamental reason why Eq. (A12) holds for RG circuits is that *neither* strategy (nor any other strategy, as we show below) succeeds in producing an intermediate tensor \mathscr{T}_{\min} with a number of legs that is sublinear in N. The time-like strategy can be seen to fail by considering the extreme limit in which \mathcal{P} is empty: The number of gate wires exiting \mathscr{T}_{\min} is then determined by the number of edges connecting bags in \mathcal{U} to bags in \mathcal{C} , and this number is guaranteed to scale linearly with the size of \mathcal{C} whenever the underlying graph \mathcal{G} is a good expander, as is the case for random regular graphs. The above reasoning is somewhat heuristic, but it can readily be turned into a proof of Eq. (A12). Specifically, we need to show that with probability (over the considered class of graphs considered) approaching 1 for large N, no contraction strategy can yield \mathscr{T}_{\min} with rank $r_{\min} < cN$ for some constant c.

If we consider \mathscr{T}_C as a graph (tensors \rightarrow nodes and legs \rightarrow edges) and denote the set of black nodes in Fig. A16 as V, the rank of \mathscr{T}_{\min} is the size of the edge-boundary of V, denoted by $|\partial V|$, and Eq. (A12) will be true as long as $|\partial V| \ge cN$. The edge boundary ∂V contains all colored edges that originate from \mathcal{C} and terminate on vertices in \mathcal{U} or unfilled vertices in \mathcal{P} . The number of such edges is lower-bounded by $\max(0, |\partial \mathcal{C}| - d|\mathcal{P}|)$. Since every bag in \mathcal{P} also contributes at least one black edge to ∂V (not already counted in the colored edges considered above)



FIG. A16. Example tensor network for a depth-3 random circuit on 10 qubits, with a possible intermediate tensor in the contraction process denoted as the collection of black tensors (e.g. they will all be contracted together into a single tensor during the contraction process). There is always an intermediate tensor built by contracting at least 1/3 and at most 2/3 of the original tensors, and in this example we are depicting an intermediate tensor built by contracting exactly half (Nd/2 = 15) the original tensors. Each grey disk, which we refer to as a bag, is associated with a particular qubit and contains all tensors having legs originating from that qubit's wire. Those bags can be subdivided into sets C, U, and \mathcal{P} , according to whether they are fully contracted, completely uncontracted, or partially contracted.

we conclude that

$$|\partial V| \ge |\mathcal{P}| + \max(0, |\partial \mathcal{C}| - d|\mathcal{P}|). \tag{A14}$$

The first and second terms in Eq. (A14) capture the costs of attempting to contract the tensor network in a time-like (Schrödinger) or space-like direction, respectively. The edge boundary of C is constrained relative to its size by the edge isoperimetric number of \mathcal{G} , defined as

$$I(\mathcal{G}) = \min_{U} |\partial U| / |U|, \qquad (A15)$$

with U ranging over all subsets of nodes in \mathcal{G} containing at most half of the vertices in \mathcal{G} . Either \mathcal{C} or its complement satisfies the constraint of having at most half of the vertices in \mathcal{G} . The complement of \mathcal{C} is lower-bounded in size by N/3 (because |V| < 2Nd/3) and therefore

$$|\partial C| \ge I(\mathcal{G}) \min(|\mathcal{C}|, N/3). \tag{A16}$$

The notion that random regular graphs are (with high probability) good expanders can be formalized in the following theorem by Bollobás [59] regarding the isoperimetric number of \mathcal{G} :

Good edge expansion of random d-regular graphs: Consider the distribution of d-regular graphs on N nodes sampled uniformly at random, and define $\eta(d) =$ $2\sqrt{(\log 2)/d}$. For all $d \geq 3$, and with probability approaching 1 as $N \to \infty$, the isoperimetric number $I(\mathcal{G})$ of a graph \mathcal{G} sampled from this distribution is bounded below as:

$$I(\mathcal{G}) \ge \frac{d}{2} (1 - \eta(d)).$$
(A17)

Combining Eq. (A17) with Eqs. (A14, A16) yields the lower bound

$$|\partial V| \ge |\mathcal{P}| + d \times \max\left(0, \frac{\min(|\mathcal{C}|, N/3)[1 - \eta(d)]}{2} - |\mathcal{P}|\right).$$
(A18)

Recall that by the definition of \mathscr{T}_{\min} , the size of V is constrained to satisfy

$$\frac{dN}{3} \le |V| \le \frac{2dN}{3}.\tag{A19}$$

Since each bag in C contributes exactly d vertices to V while each bag in \mathcal{P} contributes at most d-1, we conclude that

$$|\mathcal{C}| \ge \frac{N}{3} - |\mathcal{P}|,\tag{A20}$$

from which we can further bound $|\partial V|$ as

$$|\partial V| \ge |\mathcal{P}| + d \times \max\left(0, \frac{[N/3 - |\mathcal{P}|][1 - \eta(d)]}{2} - |\mathcal{P}|\right).$$
(A21)

Upon varying $|\mathcal{P}|$, the r.h.s. is minimized (for $d \geq 3$) when the second argument of the max() function vanishes, ultimately giving

$$|\partial V| \ge \frac{N[1 - \eta(d)]}{9}.$$
 (A22)

Note that we have not attempted to make the bound even reasonably tight, and we expect it is possible to derive a bound in which the r.h.s. tends to N as $d \to \infty$.

B. Upper bound

The previous section demonstrates that the asymptotic contraction complexity density \mathscr{C}_d is finite, but does not address how the density approaches the worst-case upper bound from statevector simulation ($\mathscr{C}_d \to 1$) as the depth increases. Fig. A17 shows numerical evidence that the complexity density saturates, and also that the saturated value quickly approaches 1 as d increases. It is natural to ask precisely how $\mathscr{C}_d \to 1$ as $d \to \infty$: Does $1 - \mathscr{C}_d$ vanish smoothly as $d \to \infty$, and if so does it decay polynomially or exponentially? Or does it vanish abruptly at some critical value $d = d_c$?



FIG. A17. Complexity density as a function of N for circuit depths d = 4, 6, 8, 10, showing saturation to a constant as $N \to \infty$. Each point is the mean complexity density over 20 random circuits (shaded regions represent one standard-deviation).

Here we show that $1 - \mathcal{C}_d$ cannot vanish abruptly by proving that individual circuit instances obey the upper bound

$$\mathscr{C}_d \le 1 - 1/2^d. \tag{A23}$$

This bound leaves open the possibility that $1 - \mathcal{C}_d$ vanishes exponentially as $d \to \infty$; we find this scenario likely but have no proof of it. The proof of Eq. (A23) is by analysis of an explicit contraction ordering inspired by the qubit reuse algorithm described in Ref. [60].

Pick any pair of qubits j_1, k_1 that are gated together in the final layer of gates and contract all tensors corresponding to gates in those qubits' past causal cone. A representative example of such a causal cone is shown for a 10 qubit depth-3 circuit in Fig. A18. Denote the set of output qubits by $\mathcal{O}_1 = \{j_1, k_1\}$ and the collection of input qubits in the past causal cone of \mathcal{O}_1 by \mathcal{I}_1 . It is easy to see that these sets satisfy

$$|\mathcal{O}_1| = 2 \tag{A24}$$

$$|\mathcal{I}_1| \le \min(2^d, N) \tag{A25}$$

This contraction can be performed in a time-like direction with at most $|\mathcal{I}_1|$ legs protruding from any intermediate tensor (corresponding to unterminated wires of the input qubits in \mathcal{I}_1). Note that the final tensor formed this way has at most $|\mathcal{I}_1| - 2$ open legs, since we close the two outputs associated with qubit j_1 and k_1 . Now we pick a new pair of output qubits $j_2, k_2 \notin \mathcal{O}_1$ that are gated together in the final layer, define $\mathcal{O}_2 = \{j_2, k_2\} \cup \mathcal{O}_1$, and define \mathcal{I}_2 to be the set of all qubits in the past casual cone of \mathcal{O}_2 . Since $\mathcal{I}_2 \backslash \mathcal{I}_1$ has at most 2^d qubits, continuing the contraction process in a time-like direction with all gates in \mathcal{I}_2 that have not already been contracted cannot add



FIG. A18. Light-cone based contraction ordering yielding the upper bound in Eq. (A23).

more than 2^d legs to the existing tensor. Therefore

$$|\mathcal{O}_2| = 4 \tag{A26}$$

$$|\mathcal{I}_2| \le \min(N, 2 \times 2^d), \tag{A27}$$

and no intermediate tensor can have more than $|\mathcal{I}_2| - |\mathcal{O}_1|$ legs (the " $-|\mathcal{O}_1|$ " contribution because 2 indices corresponding to the outputs at qubits in \mathcal{O}_1 have been fixed). Iterating this process, we find that at stage ℓ

$$\mathcal{O}_{\ell}| = 2 \times \ell \tag{A28}$$

$$|\mathcal{I}_{\ell}| \le \min(N, \ell \times 2^d), \tag{A29}$$

and no intermediate tensor can have had more than $|\mathcal{I}_{\ell}| - |\mathcal{O}_{\ell-1}|$ legs. At some point in this process the size of \mathcal{I}_{ℓ} will be equal to N, but that cannot happen unless $\ell \geq N/2^d$. At this stage, the largest number of legs in



FIG. A19. Models of the exact contraction cost for both 2D (top) and RG (bottom) circuits. (a,d) show the exact contraction cost estimated using cotengra for 2D and RG circuits, respectively. (b,e) Show slices from those plots at various N, showing collapse to the simple models described in the text at large N. (c,f) Show plots of the cost inferred from those simple models with parameters fit from panels (b,e), showing good qualitative agreement with the results in panels (a,d).

any intermediate tensor is upper bounded by

$$|\mathcal{I}_{\ell}| - |\mathcal{O}_{\ell-1}| \le N - 2(\ell - 1)$$
 (A30)

$$\leq N - 2(N/2^d - 1)$$
 (A31)

$$\leq N(1 - 1/2^d) + 2,$$
 (A32)

giving

$$\mathscr{C}_{d,N} \le 1 - 1/2^d + 2/N.$$
 (A33)

Ignoring the latter term in the limit $N \to \infty$ yields Eq. (A23).

A6. SIMPLE MODELS OF EXACT CONTRACTION COST

In Sec. III D of the manuscript we reported comparisons of achievable effective qubit numbers for 2D and RG quantum circuits. Those comparisons are based on a simplified model of memory-unconstrained contraction cost that we now describe. Figures A19(a) and A19(d) show exact contraction costs determined using cotengra for 2D circuits and RG circuits, respectively (as described in the main text).

In 2D the complexity density $\mathscr{C}_{d,N}$ is expected to scale as $\min(1, c \times d/\sqrt{N})$, with c an a priori undetermined constant. Therefore, defining $\tilde{d} = d/\sqrt{N}$, we expect a plot of $f_N(\tilde{d}) \equiv \mathscr{C}_{\tilde{d}\sqrt{N},N}$ to show collapse to a universal curve (when plotted vs. \tilde{d}) as N becomes large enough to suppress boundary effects. Figure A19(b) shows exactly this behavior, and based on the largest-N results we choose a (generous) envelope function $f(\tilde{d}) =$ $1.1 \min(1.0, 0.35\tilde{d})$ (black dashed line in Fig. A19(b)). Assuming this heuristic model of the complexity density and converting back into $\log_{10}(\text{contraction cost})$ we obtain the plot in Fig. A19(c), showing good qualitative agreement with the behavior in Fig. A19(a).

For random geometry circuits the complexity density is expected to scale independently of N for large N, approaching 1 for large d with an a priori unknown functional form. Empirically we see that \mathscr{C} grows roughly linearly until $d \approx 10$, and after this depth it saturates extremely quickly to 1. Together with the observation that the cost is small and constant at d = 1, 2 [19], this behavior motivates us to model the cost with a simple functional form $\mathscr{C}_{d,N} \approx a \times \min(1, c(d-2))$. Evaluated with the constants (a, c) = (1, 0.125), this ansatz gives the black-dashed curve in Fig. A19(e), which agrees well with the largest N calculations we performed. When converted into $\log_{10}($ contraction cost) this ansatz yields the plot in Fig. A19(f), showing good qualitative agreement with the results obtained using cotengra in Fig. A19(d).

A7. IMPACT OF GATE CHOICE ON SIMULATION HARDNESS

At sufficiently high depths, optimal TN contraction is expected to proceed in a time-like direction, exhibiting computational costs approaching statevector simulation. In this limit, gate choice will have minimal impact on the cost of exact contraction. On the other hand, at low depths the optimal contraction strategy will generally not be time-like, in which case it may benefit greatly from 2Q gates having low-rank decompositions. A simple example is the 1D circuit shown in Fig. A20(a), which always admits the sideways contraction ordering shown in panel (c) with $\cot 2^d$. Decomposing the 2Q gates with Schmidt rank $r_{\rm s}$ enables a sideways contraction ordering with cost ~ $r_{\rm s}^{d/2}$. For 2Q gates with $r_{\rm s} = 4$, such as the iSWAP gate, $r_{\rm s}^{d/2} = 2^d$ and the contraction cost is the same for subfigures (c) and (d). For 2Q gates with $r_s = 2$, such as the $U_{ZZ}(\pi/2)$ gate, $r_s^{d/2} = 2^{d/2}$. Therefore, in this simple 1D example, using a rank-4 entangling gate rather than a rank-2 entangling gate effectively doubles the circuit depth.

The situation for circuits with more complicated geometries is less clear, and we have resorted to numerically studying the contraction cost dependence on gate rank by using the heuristic contraction cost optimizers provided by cotengra. Figure A21 compares the exact contraction cost of RG quantum circuits built of 2Q gates having rank-2 (circles) and rank-4 (squares) decompositions. A natural choice of rank-4 gate would be the iSWAP gate, as it has a uniform (rank-4) Schmidt spectrum and therefore resists approximation strategies based on low-rank gate approximations. However, the iSWAP gate can be made rank-2 by factoring out a SWAP gate. Factoring SWAP out of every 2Q gate would effectively map the original circuit on one random geometry and with rank-4 gates onto a new circuit on a *different* but still random geometry with rank-2 gates, and this new circuit should have a similar exact contraction cost as the original circuit with rank-2 gates. To avoid this simplification strategy we must use a rank-4 gate that remains rank-4 under SWAP factorization, and we choose a partial iSWAP for the numerical study in Fig. A21. This choice is essentially arbitrary: In the space of all possible 2Q gates, all but a set of measure zero has the aforementioned property (being rank-4 and remaining rank-4 under SWAP factorization), and so nearly any 2Q gate would lead to the same exact contraction costs given by the black squares in Fig. A21.

From Fig. A21 we see that, all else being equal, rank-4 gates should be preferred as they lead to higher contraction costs at fixed circuit depth. But all else is not equal; Quantinuum's native $U_{ZZ}(\theta)$ gate is not rank 4, and building a rank-4 gate requires at least two native gates. In principle, it should be sufficient to append a single relatively weak entangler in a different basis to our native gate (e.g., $U_{ZZ}(\theta) \rightarrow U_{ZZ}(\theta)U_{XX}(\delta)$). However, even in the limit $\delta \to 0$ our partial entangler has a nonzero average infidelity of $\epsilon_0 \sim 4.6(6) \times 10^{-4}$ [6]. Thus, one can always achieve the same circuit fidelity using just the native 2Q gate at a depth increased by a factor of $r \equiv [\varepsilon_{2Q} + (5/4)\epsilon_0]/\varepsilon_{2Q}$. Rescaling the depths of the rank-4 (black) curve in Fig. A21 by a factor of r yields a result very similar to the rank-2 curve, suggesting that the advantage (in depth reduction at fixed contraction cost) of using a rank-4 gate is largely offset by the disadvantage (in achievable depth at fixed fidelity) due to the relatively lower rank-4 gate fidelity. Therefore, we have opted to take the simpler route of applying a single $U_{ZZ}(\pi/2)$ to each qubit pair gated in each layer of our circuits (as described in Appendix A4).

A8. COMPARISON OF VARIOUS CONTRACTION-ORDER OPTIMIZERS

Finding truly optimal contraction orders for a generic tensor network is a hard problem, and the cost estimates for exact contraction given in the main manuscript are all based on heuristic algorithms deployed by cotengra for contraction order optimization. To understand how the resulting FLOP costs are situated relative to other stateof-the-art TN contraction optimization packages, we have made a variety of direct performance comparisons between cotengra, cuQuantum [61], tamaki [62], and multilevel [63]. State-of-the-art tensor network contraction algorithms used for simulating random circuit sampling use various techniques to achieve sublinear costs in the number of samples [23, 64–68], including sparse states, caching, etc. Here, we focus on single amplitude contraction optimization since very few samples (20 in this paper) are produced from each unique circuit.

The most relevant cost comparison is actual contraction time, which requires executing the contraction order obtained on classical computing hardware. However, optimizers such as tamaki and multilevel do not integrate tensor network slicing directly, which means that the contraction order is not readily usable. Another metric that can be directly compared across all four optimizers considered is the minimum width of a tree decomposition obtained by the optimizer, which determines the largest intermediate tensor size required for the contraction order found.

We choose a randomly generated 56 qubit depth-10 RG circuit, and allow the corresponding tensor network (without simplification, since tamaki and multilevel do not support it yet) to be optimized by each optimizer. Fig. A22(a) shows the width of the lowest-width tree decomposition obtained after a given amount of optimization time, and demonstrates that cuQuantum [61] and cotengra [20, 69] generally outperform tamaki and multilevel given fixed optimization time. Further, these optimizers supports slicing and tensor network simplification out of the box. However, we have not been able to successfully utilize simplification of circuits contain-



FIG. A20. Example of exact contraction cost dependence on gate rank for a 1D circuit. The circuit in (a) can be rewritten as the tensor network in (b) by assigning wires to legs and a rank-4 tensor to each 2Q gate. For sufficiently low depths, the tensor network in (b) can be contracted most efficiently by proceeding sideways. In (c) the dashed lines show intermediate tensors before and after application of tensors in a single vertical slice (black-outlined), and red circles show open indices both before and after application of all tensors in that slice. Each open index takes values in $\{0, 1\}$ and there are $\sim d$ such indices for a depth-*d* circuit, giving an overall contraction $\cos t \sim 2^d$. The rank-4 gate tensors can always be Schmidt-decomposed into two rank-3 tensors, with those two tensors sharing a leg taking values $\{1, \ldots, r_s\}$, with r_s the Schmidt rank of the gate, as shown in (d). Sideways contraction now leads to intermediate tensors with $\sim d/2$ open indices, for a total contraction cost scaling as $\sim r_s^{d/2} < 2^d$.



FIG. A21. Comparison of memory-unconstrained exact contraction costs for RG quantum circuits on 56 qubits with rank-2 and rank-4 gates. Shaded regions represent the standard deviation on \log_{10} (FLOPs) computed across 20 random circuit realizations at each depth.

ing many diagonal gates (such as U_{ZZ} gates) in cuQuantum. Therefore, we concentrate on comparing cuQuantum against cotengra for tensor networks without simplification.

To better compare cuQuantum and cotengra, we generate 10 random (N = 56, d = 10) circuit instances to capture random fluctuations in the optimized costs (due to both the differences in circuits and randomness in the optimizer). Both optimizers readily return the contraction cost in FLOP counts, which is reasonable proxy for the actual contraction time, and the results are shown in Fig. A22 (b). We observe that at very short times, cuQuantum is capable of producing good optimization results. On the other hand, while cotengra requires more time to produce good results, it is generally very competitive with cuQuantum if both are allowed $\gtrsim 100$ seconds of optimization time.

A9. ACHIEVABLE FIDELITIES WITH DMRG

Time-evolving an approximate tensor network ansatz is a promising method to simulate quantum circuits with a limited fidelity. The most well studied tensor networks in the context of quantum circuit simulations are matrix product states (MPS) and projected entanglement pair states (PEPS). For simulating transition amplitudes in random circuit sampling, the best performing algorithm that we are aware of is the variant of time-dependent DMRG presented in Ref. [3, 4], which is based around an approximate MPS representation of the full quantum state. Compared to exact simulation, the difficulty of approximate simulation — especially in the regime of sub-maximal entanglement — is much more difficult to reliably assess. This appendix elaborates on the methods used in Sec. IIIC of the manuscript, and extends them by estimating how the cost of approximate simulation grows with circuit depth for RG circuits using a combination of DMRG and the bounds on achievable MPS fidelities described in Ref. [12].

An MPS representation of a quantum state can be chosen in many different ways, and we consider blocking of the qubits into b blocks $[S_1, \ldots, S_b]$ of size $[s_1, \ldots, s_b]$, where each set S_j contains the qubits in the associated block and is assigned to a single MPS tensor. In the event that all blocks are the same size, we refer to a given blocking scheme compactly as $b \times [s]$. We denote by \mathcal{I}_j a super-index containing a single binary-valued index for each qubit in the associated block S_j . Each block can then be assigned a tensor $M_{\alpha_j,\mathcal{I}_j,\beta_j}^{(j)}$, and the full quan-



FIG. A22. Optimized contraction cost as a function of optimization time using a single CPU thread of an AMD EPYC "Milan" processor. (a) Treewidth for a single quantum circuit without slicing. (b) FLOP count for 10 quantum circuits with slicing.

tum state is approximated as a contraction over these tensors as

$$|\Psi\rangle = \sum_{\mathcal{I}_1,\dots,\mathcal{I}_b} \sum_{\alpha_1=1}^{\chi} \cdots \sum_{\alpha_{b-1}=1}^{\chi} M_{\mathcal{I}_1,\alpha_1}^{(1)} M_{\alpha_1,\mathcal{I}_2,\alpha_2}^{(2)} \cdots M_{\alpha_{b-1}\mathcal{I}_b}^{(b)} |\mathcal{S}_1\rangle \otimes \cdots \otimes |\mathcal{S}_b\rangle.$$
(A34)

Here χ is the bond dimension, which we assume to be the same for all tensors but in general need not be. An MPS of this form, and its relation to the blocking of qubits, is illustrated graphically for b = 2, 4, 7 in Fig. A23(a,b,c). A blocked MPS can always be expanded into a more standard single site MPS, with the blocked qubits corresponding to groups of adjacent single-site tensors. In this view,

the blocking effectively allows the nominal inter-block bond dimension χ to grow larger within the blocks; in the presence of inhomogeneous entanglement structure, blocking that is congruent with such structure can plausibly improve the fidelity of an MPS at fixed total resources. For a given blocking strategy $b \times [s]$, we assign qubits to blocks by using the open source hypergraph partitioning package KaHyPar to minimize the number of inter-block 2Q gates. Examples of such partitionings, and their correspondence with blocked MPS are shown in Fig. A23 for b = 2, 4, 7.

We say that a given quantum computer can be "classically spoofed" if, given a random circuit C, classical RCS can be achieved with comparable fidelity to that achieved by the quantum computer (e.g., as measured by the achievable XEB of samples) using a comparable amount of time per sample. One approach to spoofing would be to evolve an MPS through the circuit to approximate $|\Psi\rangle = C |0\rangle$, and then query the amplitudes of $|\Psi\rangle$ in the computational basis. While this approach has the benefit that sampling can be performed very directly, Ref. [4] advocated an alternate approach in which the circuit is split into lower depth circuits, for example as $C = C_2 C_1$. By approximating (through MPS evolution) both $|\Psi_1\rangle = C_1 |0\rangle$ and $|\Psi_2\rangle = C_2^{\dagger} |\boldsymbol{x}\rangle$, computational basis state amplitudes at the output of \mathcal{C} can then be computed from the overlap of those states as

$$\langle \boldsymbol{x} | C_2 C_1 | 0 \rangle = \langle \Psi_2 | \Psi_1 \rangle, \tag{A35}$$

and such calculations can then be used (e.g., in combination with rejection sampling) to draw samples from the output distribution of the circuit. An improved variation of this simulation scheme is to split the circuit into three pieces, as $C = C_2 C_M C_1$, computing amplitudes as expectation values $\langle \Psi_2 | C_M | \Psi_1 \rangle$. However, we have found that for circuits with random geometries, having even a single layer of gates in C_M increases the contraction cost dramatically, and we have only attempted simulations with the circuit decomposed as in Eq. (A35).

The DMRG calculations reported in the paper can be used to estimate the required bond dimension to achieve comparable circuit fidelities to those achieved in the experiment. In particular, one can extrapolate the error per gate as a function of bond dimension to the $\varepsilon \approx 3.2 \times 10^{-3}$ value measured in the experiment for various blocking choices at different depths. Figure (A24) shows such an extrapolation for circuits of depth 10 (where the distribution of output probabilities becomes well converged to Porter-Thomas and the exact contraction cost first becomes nearly saturated) and depth 20 (the deepest circuits for which we report experimental samples). We find only a weak dependence of the extrapolated bonddimension on the blocking choices, and in general find that bond dimensions in excess of 10^5 (10^7) are likely necessary for classical spoofing of H2 via DMRG given circuits of depth 10 (20). Note that all of the blocking results lead to error-per gate curves that are concave up, and extrapolation from relatively small bond dimensions



FIG. A23. Graph partitioning for blocked MPS simulations of a depth 5 circuit on 56 qubits. The graph from which the circuit is constructed (shown without edge coloring) is partitioned into b = 2 (a), b = 4 (b), or b = 7 (c) using KaHyPar. The objective is to minimize the number of inter-block edges, which ultimately (upon assigning blocks to MPS tensors) minimizes the number of gates that must be applied between MPS tensors.



FIG. A24. Error per gate $\varepsilon_{\rm MPS}$ in DMRG simulations for depth-10 (blue) and depth-20 (magenta) circuits using a variety of blocking strategies. The lines are a linear fit to the largest two bond dimensions plotted for each blocking strategy ($\chi = 64, 128$), and provide estimates of the bond dimension required to achieve the experimental error rates (dotted horizontal line at the bottom of the plot). The stars are lower bounds on the required bond dimension for an optimal bipartite MPS extracted from Clifford simulations (see Fig. A26 and supporting text).

may well bias the extrapolated bond dimension down relative to the true requirements.

In Ref. [12], the authors consider the bond dimension requirements to write down a bipartite MPS $|\Phi_{\text{MPS}}\rangle$ that approximates an arbitrary state $|\Psi\rangle$ with fidelity $f = |\langle \Phi_{\text{MPS}} | \Psi \rangle|^2$. In particular, they show that the fidelity is bounded above as $f^2 \leq \chi \operatorname{Tr}(\rho^2)$, where ρ is the reduced density matrix of the exact state $|\Psi\rangle$ on either side of the bipartition. Since the computation of amplitudes by evolving two MPSs toward the middle of the circuit achieves an effective simulation fidelity $F \sim f^2$ (being diminished by the loss of fidelity of both the forward and backward evolutions), they conclude that the simulation fidelity F achievable at fixed bond dimension is bounded above as $F \leq \chi \operatorname{Tr}(\rho^2)$.

Discrepant accounts of the relationship between the achievable MPS fidelity and the associated F_{XEB} have been reported in the literature (see Refs. [4] and [12]), though we note that the fidelities here are sufficiently large that the discrepancies between these two references are relatively inconsequential. We also performed numerical simulations for our circuits in the range of fidelities relevant to the experiment, and find that $F = f^2$ serves as an excellent proxy for the achievable values of $F_{\rm XEB}$ from sampling based on closed-simulation amplitude calculations. For these calculations, we consider RG circuits on 24 qubits at depth 10 (at which point the output distribution of the exact circuits is well converged to the Porter-Thomas distribution). We sample a random bitstring \boldsymbol{x} , and then evolve $|0\rangle$ (forward) and $|x\rangle$ (backwards) to the midpoint of the circuit. Both states are then optimally approximated by a bond dimension χ MPS via direct singular-value decomposition (SVD), and we record both the estimated probability for bitstring \boldsymbol{x} (squared overlap of the two MPSs) and the fidelity $F = f_0 f_{\boldsymbol{x}}$, where $f_{0(\boldsymbol{x})}$ is computed from the discarded weight of the SVD for the time-evolved $|0(\mathbf{x})\rangle$ state. We compute the amplitudes of 1000 randomly chosen bitstrings for 100 random circuits (for a



FIG. A25. Achievable $F_{\rm XEB}$ by sampling from bitstrings whose amplitudes have been calculated using a closed MPS simulation at fidelity F. The various curves represent the achievable improvements by post-processing the sampled bitstrings, showing that fidelity improvements by post-selecting on large probabilities require exponential post-selection overhead (i.e. the ratio of $F_{\rm XEB}/F$ increases roughly linearly as the fraction of retained data, α , is decreased exponentially.)

total of 100,000 amplitudes), and then for each circuit we estimate the achievable F_{XEB} by resampling from the associated list of 1000 estimated probabilities and computing F_{XEB} from those samples. In Fig. A25, the lowest (bluest, $\alpha = 1$) solid curve is a parametric plot of $F(\chi)$ versus $F_{\rm XEB}(\chi)$ averaged over the 100 sampled circuits (with the shaded region indicating the standard error on the mean over those circuits), showing excellent correlation. In general, various post-processing strategies might be employed to increase the achievable $F_{\rm XEB}$ given the list of estimated probabilities. The other curves ($\alpha < 1$) in Fig. A25 are obtained by post-processing the MPS estimates of the 1000 bitstring probabilities computed for each circuit by retaining just the largest $\alpha \times 1000$ largest samples (similar to the top-k post-processing method described in Ref. [13]). While such post-processing can produce F_{XEB} values larger than the achieved simulation fidelity F, the linear growth of F_{XEB} apparent in Fig. A25 as α is decreased exponentially suggests that the retained fraction of bitstrings must shrink exponentially in the desired multiplicative enhancement of the fidelity. This behavior is expected for exact sampling given the exponential decay of the exact Porter-Thomas distribution, which makes sampling bitstrings with probabilities R times larger than $1/2^N$ exponentially unlikely in R. We attribute the persistence of this behavior in approximate sampling to the distribution of approximated probabilities also having an exponential tail.

Given the exponentially large cost of enhancing F_{XEB} via post-processing, we see no obvious better strategy to achieve (on average across circuits) a given XEB



FIG. A26. Clifford simulations of the average bipartite purity (converted into a minimum bond dimension χ using Eq. (A36)) for our circuits at various system sizes. All curves are averaged over 100 random geometries and 10 random assignments of 1Q gates per geometry, with the optimal blocking determined for each geometry independently. The black curve shows simulations with Haar-random 1Q gates for N = 16, confirming the equivalence with averages over Clifford circuits.

score F_{XEB} than simply choosing a bond dimension large enough that the MPS fidelity $F = f_0 f_x$ is comparable to F_{XEB} . Returning to the analysis of Ref. [12] and the bound $F \leq \chi \operatorname{Tr}(\rho^2)$ derived therein, one should therefore use a bond dimension bounded below as

$$\chi \ge F/\overline{\operatorname{Tr}(\rho^2)},$$
 (A36)

where the overline denotes an average over circuits. As a result of the 2-design property of the Clifford group, $Tr(\rho^2)$ can be computed efficiently for our circuits by replacing the Haar random 1Q gates with i.i.d. random 1Q Clifford gates (see for example Ref. [70]), and then performing the average numerically using efficient Clifford simulations. Lower bounds on the bond dimension from such simulations are shown for $n \in \{16, 24, 32, 40, 48, 56\}$ in Fig. A26. For 56 qubits, this bound is also shown in Fig. A24 at depths d = 10, 20 (blue and magenta stars, respectively). In practice, a DMRG simulation may under perform relative to this bound for several reasons, including: (1) The bound is only tight for states with a flat Schmidt spectrum, which will not be encountered for the non-Clifford circuits considered in this manuscript, and (2) DMRG is a greedy algorithm that may not produce the globally optimal MPS. Indeed, we see that for a variety of blocking strategies, extrapolation of the DMRG results to determine what bond dimension is required to achieve the experimentally measured fidelities indicates that the bound is *not* saturated in practice (at least in our implementation of the DMRG algorithm), requiring bond dimensions in the neighborhood of 10^5 even for depth-10 circuits. While it is not entirely clear how far the

bond dimension in DMRG simulations could be pushed in practice, we note that the largest MPS-based simulation performed to date (by a large margin) used a bond dimension of $2^{16} = 65,536$ [71]. Utilizing approximately 1000 tensor-processing-unit cores, this calculation took on the order of minutes for a single MPS optimization, of which many are required to simulate even a depth-10 circuit. While this time could surely be brought down to some extent, we note that the deeper circuits here require *much* larger bond dimensions (e.g. the magenta lines and star in Fig. A24). Moreover, slight modifications of the 1Q gate set can lower the depth at which the purity saturates to its Haar-random (~ $1/2^{N/2-1}$)

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value. For example, fixing the 1Q gates to be $\pi/2$ rotations about axes in the xy plane of the Bloch sphere (as in Ref. [12]) avoids situations — encountered early in circuits with the Haar-random SU(2) gates used here — in which the 1Q gates leave the $|0\rangle$ state close to the south or north pole of the Bloch sphere (which then reduces the amount of entanglement the $U_{ZZ}(\pi/2)$ gates can generate). Simulations using a Clifford 1Q gate set restricted to such rotations yield the dotted line in Fig. A26, showing that even depth-12 circuits (the same depth at which the cost of memory-unconstrained contraction saturates) can require near-maximal bond dimensions.

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